

# SupIRBuck™

## HIGHLY EFFICIENT

## INTEGRATED 3A SYNCHRONOUS BUCK REGULATOR

### Features

- Wide Input Voltage Range 1.5V to 21V
- Wide Output Voltage Range 0.7V to 0.9\*Vin
- Continuous 3A Load Capability
- Integrated Bootstrap-diode
- High Bandwidth E/A for excellent transient performance
- Programmable Switching Frequency up to 1.2MHz
- Programmable Over Current Protection
- PGood output
- Hiccup Current Limit
- Precision Reference Voltage (0.7V, +/-1%)
- Programmable Soft-Start
- Enable Input with Voltage Monitoring Capability
- Enhanced Pre-Bias Start-up
- Seq input for Tracking applications
- -40°C to 125°C operating junction temperature
- Thermal Protection
- Multiple current ratings in pin compatible footprint
- 5mm x 6mm Power QFN Package, 0.9 mm height
- Lead-free, halogen-free and RoHS compliant

### Applications

- Server Applications
- Storage Applications
- Embedded Telecom Systems
- Distributed Point of Load Power Architectures

### Description

The IR3843A **SupIRBuck™** is an easy-to-use, fully integrated and highly efficient DC/DC synchronous Buck regulator. The MOSFETs co-packaged with the on-chip PWM controller make IR3843A a space-efficient solution, providing accurate power delivery for low output voltage applications.

IR3843A is a versatile regulator which offers programmability of start up time, switching frequency and current limit while operating in wide input and output voltage range.

The switching frequency is programmable from 250kHz to 1.2MHz for an optimum solution.

It also features important protection functions, such as Pre-Bias startup, hiccup current limit and thermal shutdown to give required system level security in the event of fault conditions.

- Netcom Applications
- Computing Peripheral Voltage Regulators
- General DC-DC Converters

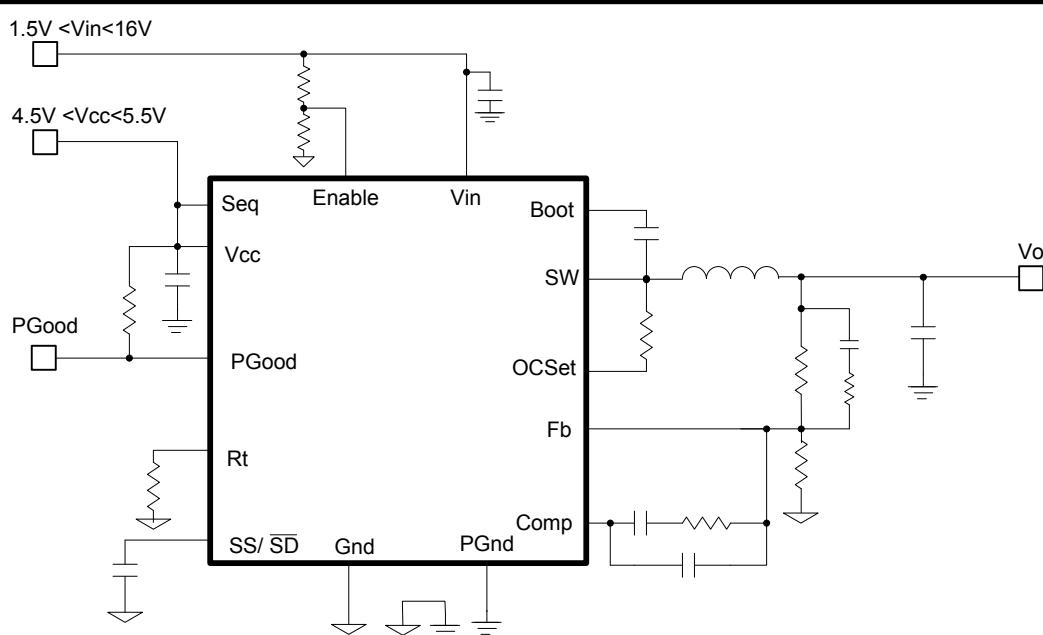


Fig. 1. Typical application diagram

## ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to GND unless otherwise specified)

- Vin ..... -0.3V to 25V
- Vcc ..... -0.3V to 8V (Note2)
- Boot ..... -0.3V to 33V
- SW ..... -0.3V to 25V(DC), -4V to 25V(AC, 100ns)
- Boot to SW ..... -0.3V to Vcc+0.3V (Note1)
- OCSet ..... -0.3V to 30V, 30mA
- Input / output Pins ..... -0.3V to Vcc+0.3V (Note1)
- PGND to GND ..... -0.3V to +0.3V
- Storage Temperature Range ..... -55°C To 150°C
- Junction Temperature Range ..... -40°C To 150°C (Note2)
- ESD Classification ..... JEDEC Class 1C
- Moisture sensitivity level.....JEDEC Level 2@260 °C (Note5)

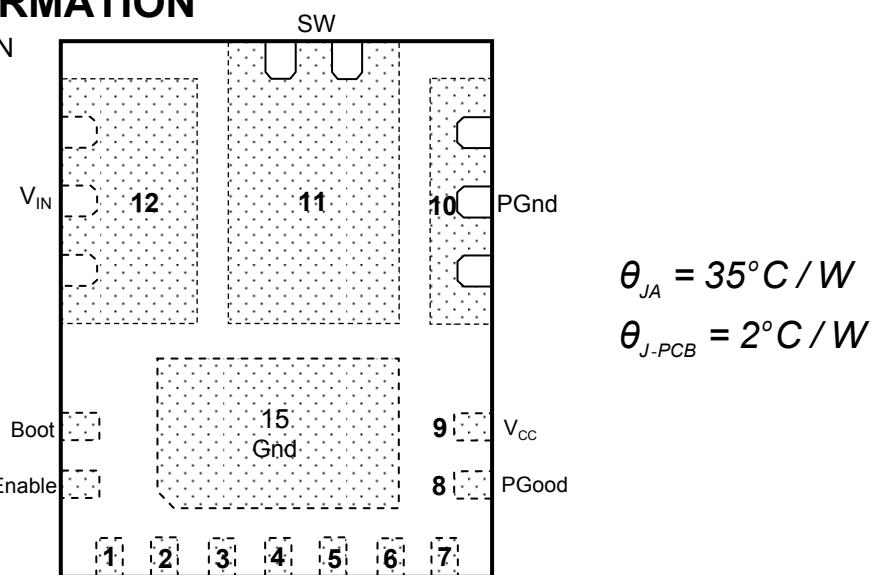
**Note1:** Must not exceed 8V

**Note2:** Vcc must not exceed 7.5V for Junction Temperature between -10°C and -40°C

*Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied.*

## PACKAGE INFORMATION

5mm x 6mm POWER QFN



## ORDERING INFORMATION

Seq FB COMP Gnd Rt SS OCSet

PACKAGE DESIGNATOR	PACKAGE DESCRIPTION	PIN COUNT	PARTS PER REEL
M	IR3843AMTRPbF	15	4000
M	IR3843AMTR1PbF	15	750

## Block Diagram

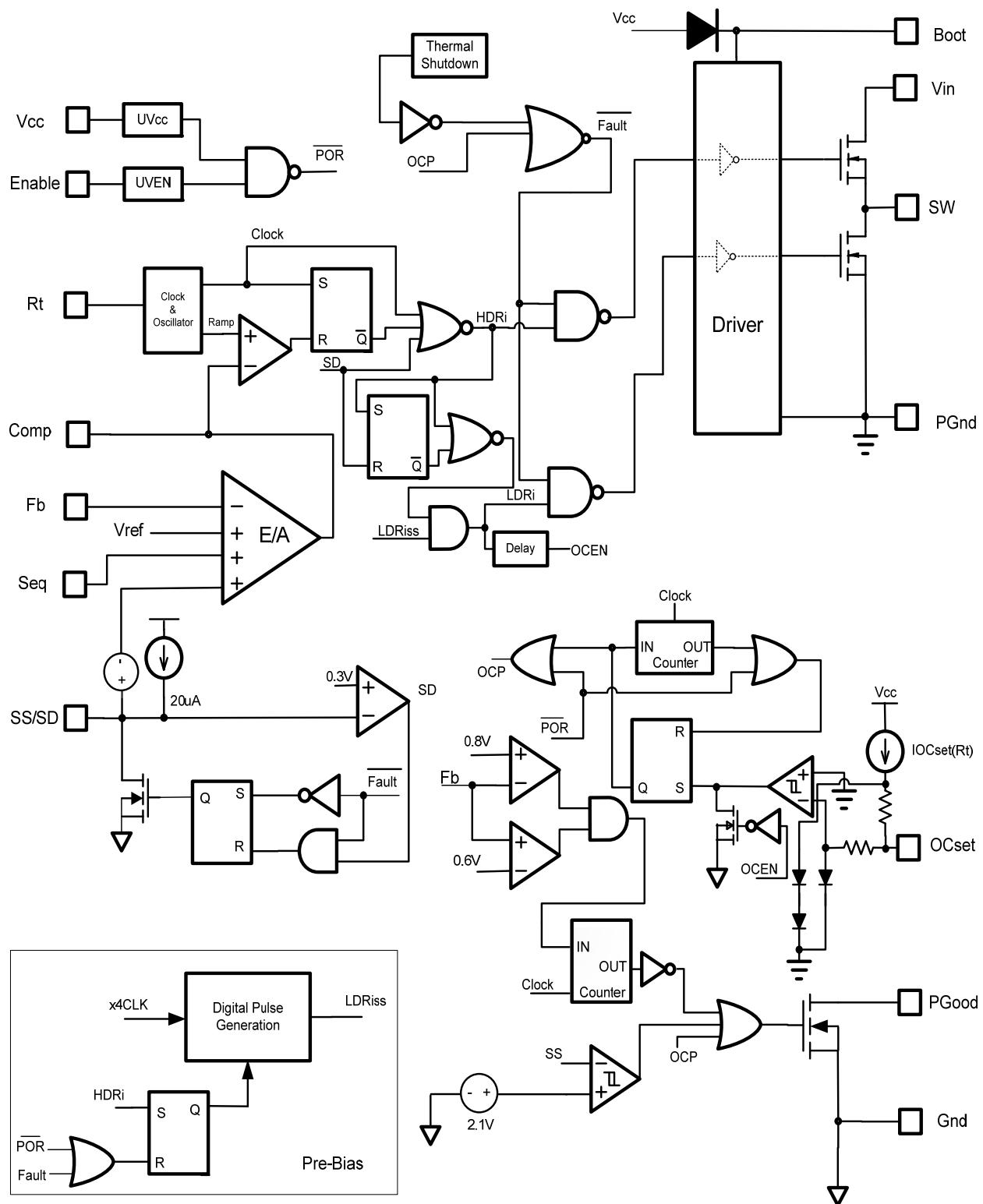


Fig. 2. Simplified block diagram of the IR3843A

## Pin Description

Pin	Name	Description
1	Seq	Sequence pin. Use two external resistors to set Simultaneous Power up sequencing. If this pin is not used connect to Vcc.
2	Fb	Inverting input to the error amplifier. This pin is connected directly to the output of the regulator via resistor divider to set the output voltage and provide feedback to the error amplifier.
3	Comp	Output of error amplifier. An external resistor and capacitor network is typically connected from this pin to Fb pin to provide loop compensation.
4	Gnd	Signal ground for internal reference and control circuitry.
5	Rt	Set the switching frequency. Connect an external resistor from this pin to Gnd to set the switching frequency.
6	SS/SD	Soft start / shutdown. This pin provides user programmable soft-start function. Connect an external capacitor from this pin to Gnd to set the start up time of the output voltage. The converter can be shutdown by pulling this pin below 0.3V.
7	OCSet	Current limit set point. A resistor from this pin to SW pin will set the current limit threshold.
8	PGood	Power Good status pin. Output is open drain. Connect a pull up resistor from this pin to Vcc. If unused, it can be left open.
9	V <sub>CC</sub>	This pin powers the internal IC and the drivers. A minimum of 1uF high frequency capacitor must be connected from this pin to the power ground (PGnd).
10	PGnd	Power Ground. This pin serves as a separated ground for the MOSFET drivers and should be connected to the system's power ground plane.
11	SW	Switch node. This pin is connected to the output inductor.
12	V <sub>IN</sub>	Input voltage connection pin.
13	Boot	Supply voltage for high side driver. A 0.1uF capacitor must be connected from this pin to SW.
14	Enable	Enable pin to turn on and off the device. Use two external resistors to set the turn on threshold (see Enable section). Connect this pin to Vcc if it is not used.
15	Gnd	Signal ground for internal reference and control circuitry.

## Recommended Operating Conditions

Symbol	Definition	Min	Max	Units
$V_{in}$	Input Voltage	1.5	21*	V
$V_{cc}$	Supply Voltage	4.5	5.5	
Boot to SW	Supply Voltage	4.5	5.5	
$V_o$	Output Voltage	0.7	0.9* $V_{in}$	
$I_o$	Output Current	0	3	A
$F_s$	Switching Frequency	225	1320	kHz
$T_j$	Junction Temperature	-40	125	°C

\* SW must not exceed the Abs Max Rating (25V)

## Electrical Specifications

Unless otherwise specified, these specification apply over  $4.5V < V_{cc} < 5.5V$ ,  $V_{in} = 12V$ ,  $0^{\circ}C < T_j < 125^{\circ}C$ .  
Typical values are specified at  $T_a = 25^{\circ}C$ .

Parameter	Symbol	Test Condition	Min	TYP	MAX	Units
<b>Power Loss</b>						
Power Loss	$P_{loss}$	$V_{cc}=5V$ , $V_{in}=12V$ , $V_o=1.8V$ , $I_o=3A$ , $F_s=600kHz$ , $L=2.2uH$ , Note4		0.682		W
<b>MOSFET <math>R_{ds(on)}</math></b>						
Top Switch	$R_{ds(on)}_{Top}$	$V_{Boot}-V_{sw}=5V$ , $I_o=3A$ , $T_j=25^{\circ}C$		24.5	32	mΩ
Bottom Switch	$R_{ds(on)}_{Bot}$	$V_{cc}=5V$ , $I_o=3A$ , $T_j=25^{\circ}C$		24.5	32	
<b>Reference Voltage</b>						
Feedback Voltage	$V_{FB}$			0.7		V
Accuracy		$0^{\circ}C < T_j < 125^{\circ}C$	-1.0		+1.0	%
		$-40^{\circ}C < T_j < 125^{\circ}C$ , Note3	-2.0		+2.0	
<b>Supply Current</b>						
$V_{cc}$ Supply Current (Standby)	$I_{CC(Standby)}$	SS=0V, No Switching, Enable low			500	μA
$V_{cc}$ Supply Current (Dyn)	$I_{CC(Dyn)}$	SS=3V, $V_{cc}=5V$ , $F_s=500kHz$ Enable high		10		mA
<b>Under Voltage Lockout</b>						
$V_{cc}$ -Start-Threshold	$V_{cc\_UVLO\_Start}$	Vcc Rising Trip Level	3.95	4.15	4.35	V
$V_{cc}$ -Stop-Threshold	$V_{cc\_UVLO\_Stop}$	Vcc Falling Trip Level	3.65	3.85	4.05	
Enable-Start-Threshold	$Enable\_UVLO\_Start$	Supply ramping up	1.14	1.2	1.36	
Enable-Stop-Threshold	$Enable\_UVLO\_Stop$	Supply ramping down	0.9	1.0	1.06	
Enable leakage current	$I_{en}$	Enable=3.3V			15	μA

### Electrical Specifications (continued)

Unless otherwise specified, these specifications apply over  $4.5V < V_{cc} < 5.5V$ ,  $V_{in} = 12V$ ,  $0^\circ C < T_j < 125^\circ C$ .  
Typical values are specified at  $T_a = 25^\circ C$ .

Parameter	Symbol	Test Condition	Min	TYP	MAX	Units
<b>Oscillator</b>						
Rt Voltage			0.685	0.7	0.735	V
Frequency	Fs	Rt=59K	225	250	275	kHz
		Rt=28.7K	450	500	550	
		Rt=11.5K, Note4	1080	1200	1320	
Ramp Amplitude	Vramp	Note4		1.8		Vp-p
Ramp Offset	Ramp (os)	Note4		0.6		V
Min Pulse Width	Dmin(ctrl)	Note4		100		ns
Fixed Off Time		Note4		130	200	
Max Duty Cycle	Dmax	Fs=250kHz	92			%
<b>Error Amplifier</b>						
Input Offset Voltage	Vos	Vfb-Vseq, Vseq=0.8V	-10	0	+10	mV
Input Bias Current	IFb(E/A)		-1		+1	µA
Input Bias Current	IVp(E/A)		-1		+1	
Sink Current	Isink(E/A)		0.40	0.85	1.2	mA
Source Current	Isource(E/A)		8	10	13	
Slew Rate	SR	Note4	7	12	20	
Gain-Bandwidth Product	GBWP	Note4	20	30	40	MHz
DC Gain	Gain	Note4	100	110	120	dB
Maximum Voltage	Vmax(E/A)	Vcc=4.5V	3.4	3.5	3.75	V
Minimum Voltage	Vmin(E/A)			120	220	mV
Common Mode Voltage		Note4	0		1	V
<b>Soft Start/SD</b>						
Soft Start Current	ISS	Source	14	20	26	µA
Soft Start Clamp Voltage	Vss(clamp)		2.7	3.0	3.3	V
Shutdown Output Threshold	SD				0.3	
<b>Over Current Protection</b>						
OCSET Current	I <sub>OCSET</sub>	Fs=250kHz	20.8	23.6	26.4	µA
		Fs=500kHz	43	48.8	54.6	
		Fs=1200kHz, Note4		121.7		
OC Comp Offset Voltage	V <sub>OFFSET</sub>	Note4	-10	0	+10	mV
SS off time	SS_Hiccup			4096		Cycles
<b>Bootstrap Diode</b>						
Forward Voltage		I(Boot)=30mA	180	260	470	mV
<b>Deadband</b>						
Deadband time		Note4	5	10	30	ns

### Electrical Specifications (continued)

Unless otherwise specified, these specification apply over  $4.5V < V_{cc} < 5.5V$ ,  $V_{in} = 12V$ ,  $0^{\circ}C < T_j < 125^{\circ}C$ .  
Typical values are specified at  $T_a = 25^{\circ}C$ .

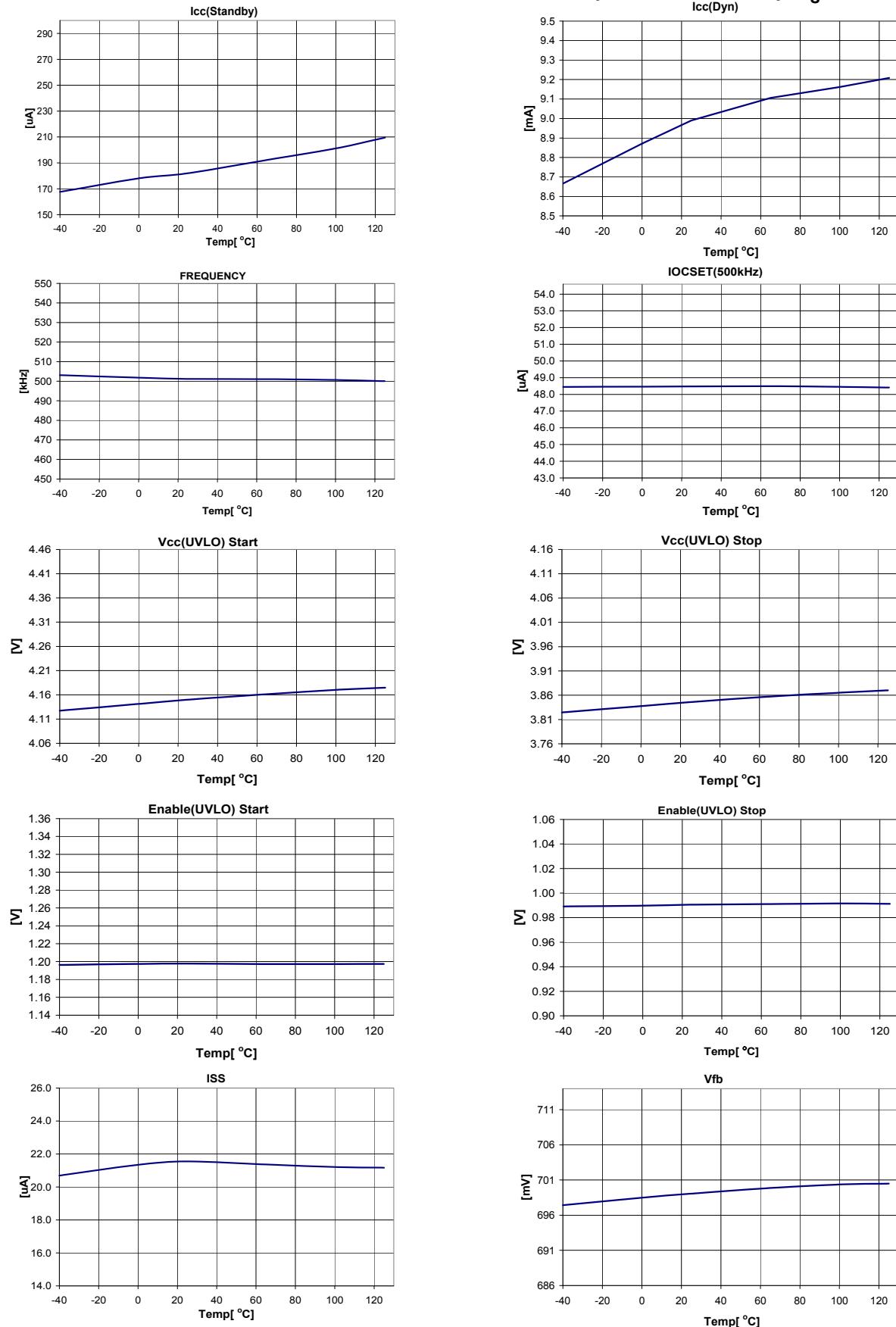
Parameter	SYM	Test Condition	Min	TYP	MAX	Units
<b>Thermal Shutdown</b>						
Thermal Shutdown		<i>Note4</i>		140		°C
Hysteresis		<i>Note4</i>		20		
<b>Power Good</b>						
Power Good upper Threshold	VPG(upper)	Fb Rising	0.77	0.805	0.840	V
Upper Threshold Delay	VPG(upper)_Dly	Fb Rising		256/Fs		s
Power Good lower Threshold	VPG(lower)	Fb Falling	0.560	0.595	0.630	V
Lower Threshold Delay	VPG(lower)_Dly	Fb Falling		256/Fs		s
Delay Comparator Threshold	PG(Delay)	Relative to charge voltage, SS rising	2	2.1	2.3	V
Delay Comparator Hysteresis	Delay(hys)	<i>Note4</i>	260	300	340	mV
PGood Voltage Low	PG(voltage)	$I_{PGood} = -5mA$			0.5	V
Leakage Current	$I_{leakage}$			0	10	μA
<b>Switch Node</b>						
SW Bias Current	$I_{sw}$	SW=0V, Enable=0V			6	μA
		SW=0V, Enable=high, SS=3V, Vseq=0V, <i>Note4</i>				

**Note3:** Cold temperature performance is guaranteed via correlation using statistical quality control. Not tested in production.

**Note4:** Guaranteed by Design but not tested in production.

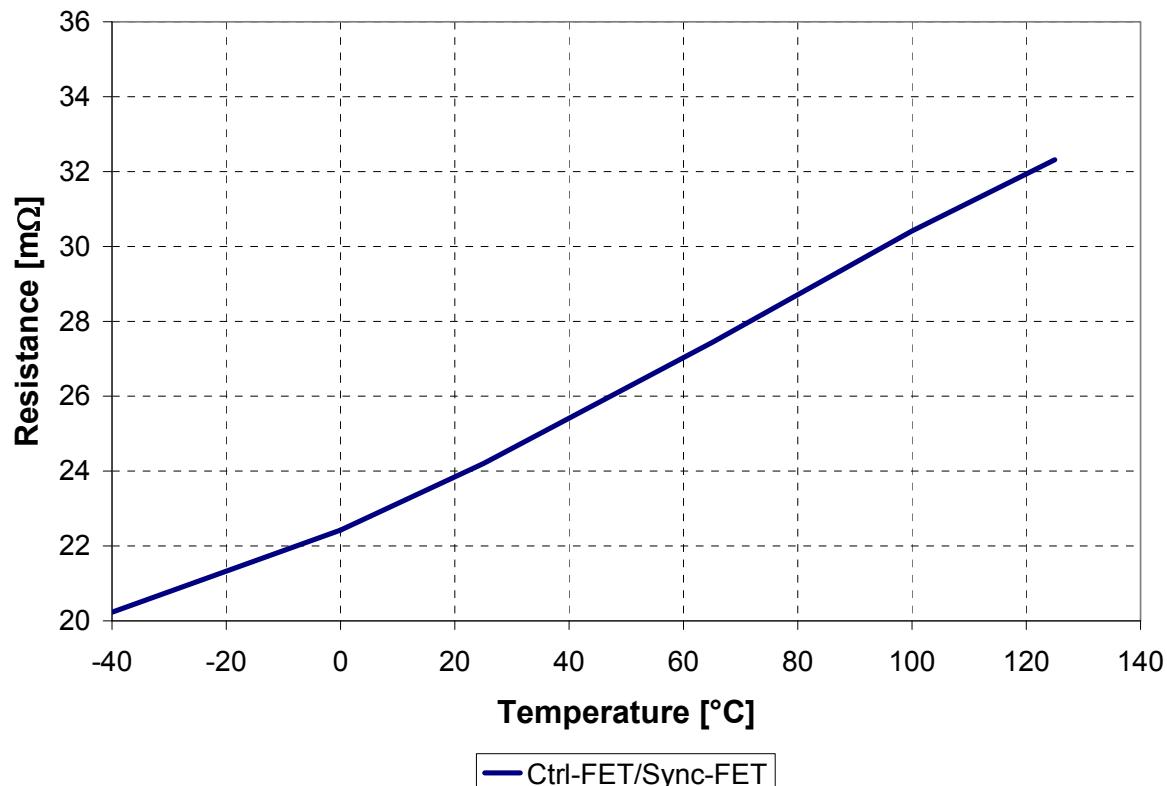
**Note5:** Upgrade to industrial/MSL2 level applies from date codes 1227 (marking explained on application note [AN1132](#) page 2).  
Products with prior date code of 1227 are qualified with MSL3 for Consumer market.

**TYPICAL OPERATING CHARACTERISTICS (-40°C - 125°C)  $F_s = 500$  kHz**



## R<sub>dson</sub> of MOSFETs Over Temperature at V<sub>cc</sub>=5V

*Note: Ctrl-FET and Sync-FET are identical.*

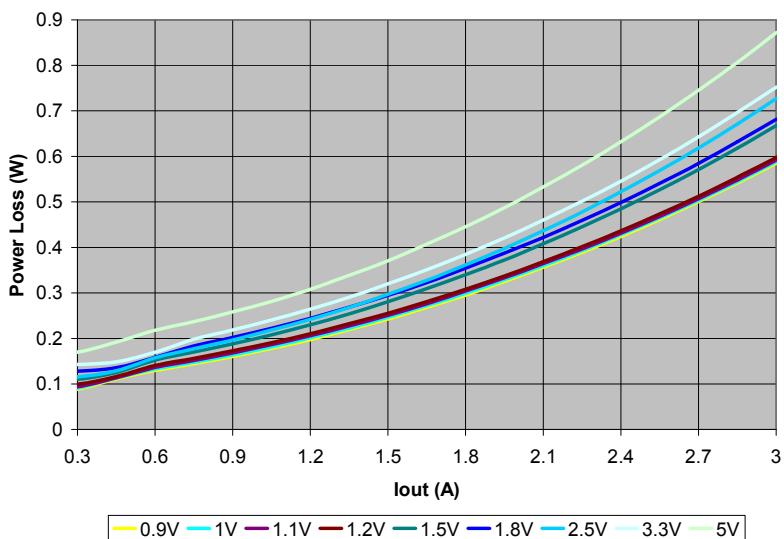
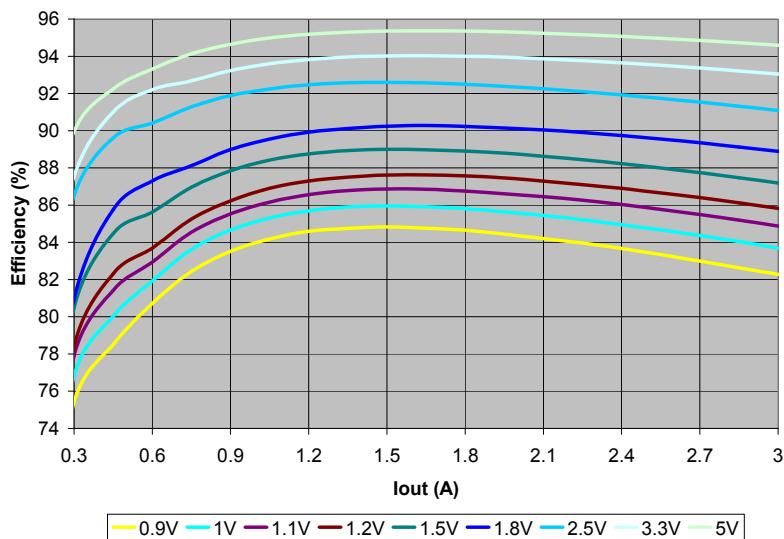


**Typical Efficiency and Power Loss Curves**

$V_{in}=12V$ ,  $V_{cc}=5V$ ,  $I_{o}=0.3A-3A$ ,  $F_s=600kHz$ , Room Temperature, No Air Flow

The table below shows the inductors used for each of the output voltages in the efficiency measurement.

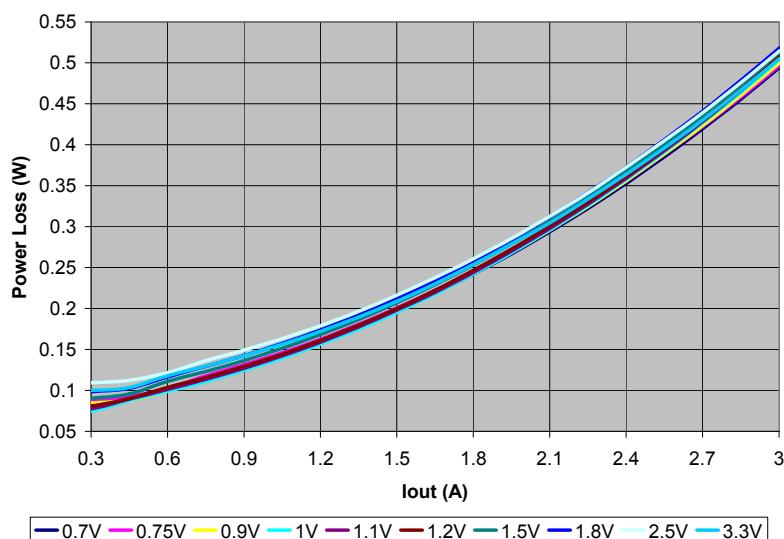
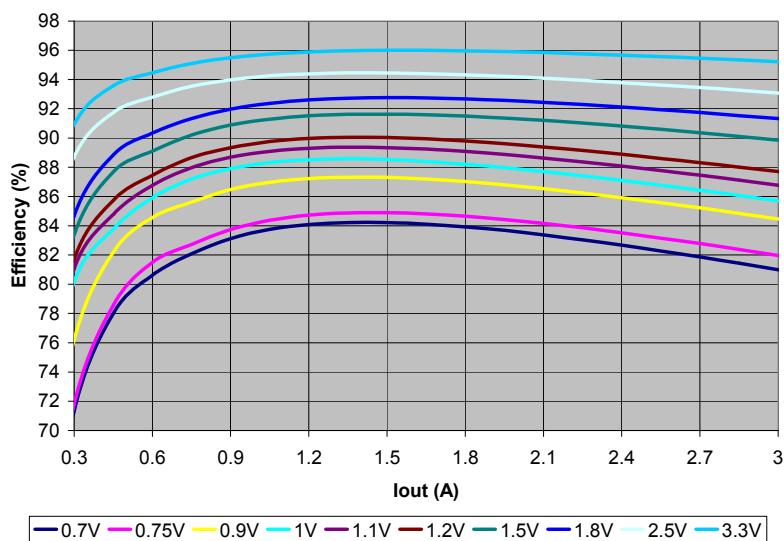
Vout (V)	L (uH)	P/N	DCR (mΩ)
0.9	1.5	PCMB065T-1R5MS	6.7
1	1.5	PCMB065T-1R5MS	6.7
1.1	1.5	PCMB065T-1R5MS	6.7
1.2	1.5	PCMB065T-1R5MS	6.7
1.5	2.2	IHLP2525EZ-01 2.2uH	13
1.8	2.2	IHLP2525EZ-01 2.2uH	13
2.5	3.3	IHLP2525EZ-01 3.3uH	19.9
3.3	3.3	IHLP2525EZ-01 3.3uH	19.9
5	4.7	IHLP2525EZ-01 4.7uH	28.9



**Typical Efficiency and Power Loss Curves**  
**V<sub>in</sub>=5V, V<sub>cc</sub>=5V, I<sub>o</sub>=0.3A-3A, F<sub>s</sub>=600kHz, Room Temperature, No Air Flow**

The table below shows the inductors used for each of the output voltages in the efficiency measurement.

V <sub>out</sub> (V)	L (uH)	P/N	DCR (mΩ)
0.7	0.82	IHLP2525EZ-01 2.2uH	4.6
0.75	0.82	IHLP2525EZ-01 2.2uH	4.6
0.9	1	PCMB065T-1R0MS	5.6
1	1.5	PCMB065T-1R5MS	6.7
1.1	1.5	PCMB065T-1R5MS	6.7
1.2	1.5	PCMB065T-1R5MS	6.7
1.5	1.5	PCMB065T-1R5MS	6.7
1.8	1.5	PCMB065T-1R5MS	6.7
2.5	1.5	PCMB065T-1R5MS	6.7
3.3	1.5	PCMB065T-1R5MS	6.7



## Circuit Description

### THEORY OF OPERATION

#### Introduction

The IR3843A uses a PWM voltage mode control scheme with external compensation to provide good noise immunity and maximum flexibility in selecting inductor values and capacitor types.

The switching frequency is programmable from 250kHz to 1.2MHz and provides the capability of optimizing the design in terms of size and performance.

IR3843A provides precisely regulated output voltage programmed via two external resistors from 0.7V to 0.9\*Vin.

The IR3843A operates with an external bias supply from 4.5V to 5.5V, allowing an extended operating input voltage range from 1.5V to 21V.

The device utilizes the on-resistance of the low side MOSFET as current sense element, this method enhances the converter's efficiency and reduces cost by eliminating the need for external current sense resistor.

IR3843A includes two low  $R_{ds(on)}$  MOSFETs using IR's HEXFET technology. These are specifically designed for high efficiency applications.

#### Under-Voltage Lockout and POR

The under-voltage lockout circuit monitors the input supply Vcc and the Enable input. It assures that the MOSFET driver outputs remain in the off state whenever either of these two signals drop below the set thresholds. Normal operation resumes once Vcc and Enable rise above their thresholds.

The POR (Power On Ready) signal is generated when all these signals reach the valid logic level (see system block diagram). When the POR is asserted the soft start sequence starts (see soft start section).

#### Enable

The Enable features another level of flexibility for start up. The Enable has precise threshold which is internally monitored by Under-Voltage Lockout (UVLO) circuit. Therefore, the IR3843A will turn on only when the voltage at the Enable pin exceeds this threshold, typically, 1.2V.

If the input to the Enable pin is derived from the bus voltage by a suitably programmed resistive divider, it can be ensured that the IR3843A does not turn on until the bus voltage reaches the desired level. Only after the bus voltage reaches or exceeds this level will the voltage at Enable pin exceed its threshold, thus enabling the IR3843A. Therefore, in addition to being a logic input pin to enable the IR3843A, the Enable feature, with its precise threshold, also allows the user to implement an Under-Voltage Lockout for the bus voltage  $V_{in}$ . This is desirable particularly for high output voltage applications, where we might want the IR3843A to be disabled at least until  $V_{in}$  exceeds the desired output voltage level.

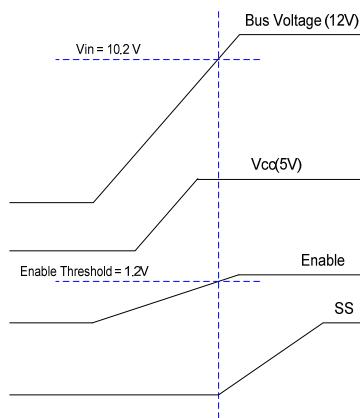


Fig. 3a. Normal Start up, Device turns on when the Bus voltage reaches 10.2V

Figure 3b. shows the recommended start-up sequence for the non-sequenced operation of IR3843A.

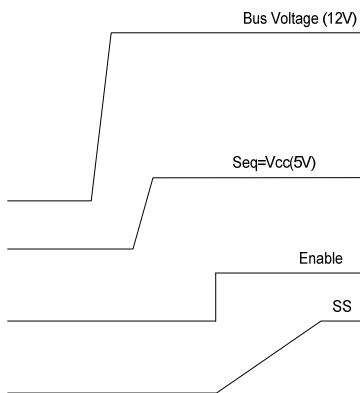


Fig. 3b. Recommended startup sequence, Non-Sequenced operation

Figure 3c. shows the recommended startup sequence for sequenced operation of IR3843A

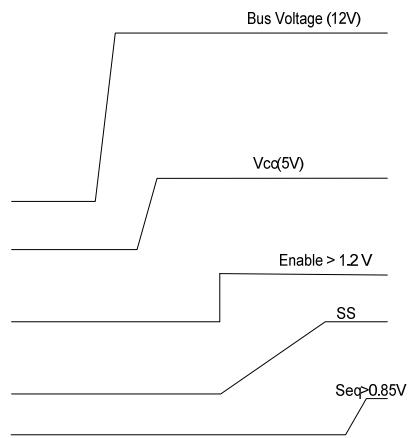


Fig. 3c. Recommended startup sequence,  
Sequenced operation

## Pre-Bias Startup

IR3843A is able to start up into pre-charged output, which prevents oscillation and disturbances of the output voltage.

The output starts in asynchronous fashion and keeps the synchronous MOSFET off until the first gate signal for control MOSFET is generated. Figure 4 shows a typical Pre-Bias condition at start up.

The synchronous MOSFET always starts with a narrow pulse width and gradually increases its duty cycle with a step of 25%, 50%, 75% and 100% until it reaches the steady state value. The number of these startup pulses for the synchronous MOSFET is internally programmed. Figure 5 shows a series of 32, 16, 8 startup pulses.

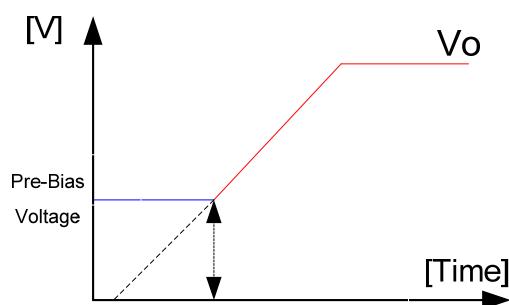


Fig. 4. Pre-Bias startup

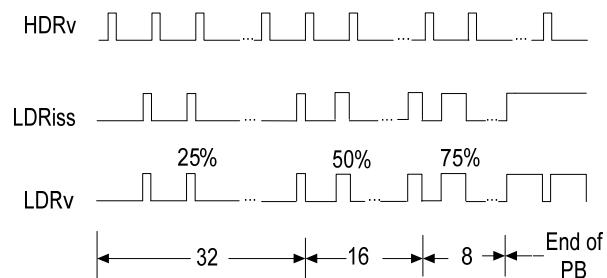


Fig. 5. Pre-Bias startup pulses

## Soft-Start

The IR3843A has a programmable soft-start to control the output voltage rise and to limit the current surge at the start-up. To ensure correct start-up, the soft-start sequence initiates when the Enable and V<sub>CC</sub> rise above their UVLO thresholds and generate the Power On Ready (POR) signal. The internal current source (typically 20 $\mu$ A) charges the external capacitor C<sub>ss</sub> linearly from 0V to 3V. Figure 6 shows the waveforms during the soft start.

The start up time can be estimated by:

$$T_{start} = \frac{(1.4 - 0.7) * C_{ss}}{20 \mu A} \quad \dots \dots \dots \quad (1)$$

During the soft start the OCP is enabled to protect the device for any short circuit and over current condition.

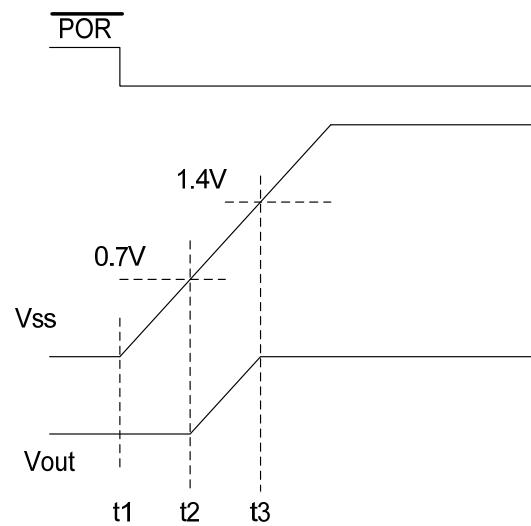


Fig. 6. Theoretical operation waveforms during soft-start

### Operating Frequency

The switching frequency can be programmed between 250kHz – 1200kHz by connecting an external resistor from  $R_t$  pin to Gnd. Table 1 tabulates the oscillator frequency versus  $R_t$ .

Table 1. Switching Frequency and  $I_{OCSet}$  vs. External Resistor ( $R_t$ )

$R_t$ (k $\Omega$ )	$F_s$ (kHz)	$I_{OCSet}$ ( $\mu$ A)
47.5	300	29.4
35.7	400	39.2
28.7	500	48.7
23.7	600	59.07
20.5	700	68.2
17.8	800	78.6
15.8	900	88.6
14.3	1000	97.9
12.7	1100	110.2
11.5	1200	121.7

### Shutdown

The IR3843A can be shutdown by pulling the Enable pin below its 1 V threshold. This will tri-state both, the high side driver as well as the low side driver. Alternatively, the output can be shutdown by pulling the soft-start pin below 0.3V. Normal operation is resumed by cycling the voltage at the Soft Start pin.

### Over-Current Protection

The over current protection is performed by sensing current through the  $R_{DS(on)}$  of low side MOSFET. This method enhances the converter's efficiency and reduces cost by eliminating a current sense resistor. As shown in figure 7, an external resistor ( $R_{OCSet}$ ) is connected between OCSet pin and the switch node (SW) which sets the current limit set point.

An internal current source sources current ( $I_{OCSet}$ ) out of the OCSet pin. This current is a function of the switching frequency and hence, of  $R_t$ .

$$I_{OCSet}(\mu\text{A}) = \frac{1400}{R_t(\text{k}\Omega)} \dots\dots\dots(2)$$

Table 1. shows  $I_{OCSet}$  at different switching frequencies. The internal current source develops a voltage across  $R_{OCSet}$ . When the low side MOSFET is turned on, the inductor current flows through the Q2 and results in a voltage at OCSet which is given by:

$$V_{OCSet} = (I_{OCSet} * R_{OCSet}) - (R_{DS(on)} * I_L) \dots\dots\dots(3)$$

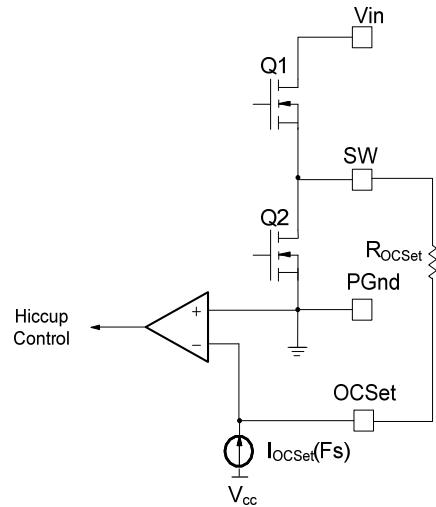


Fig. 7. Connection of over current sensing resistor

An over current is detected if the OCSet pin goes below ground. Hence, at the current limit threshold,  $V_{OCSet}=0$ . Then, for a current limit setting  $I_{Limit}$ ,  $R_{OCSet}$  is calculated as follows:

$$R_{OCSet} = \frac{R_{DS(on)} * I_{Limit}}{I_{OCSet}} \dots\dots\dots(4)$$

An overcurrent detection trips the OCP comparator, latches OCP signal and cycles the soft start function in hiccup mode.

The hiccup is performed by shorting the soft-start capacitor to ground and counting the number of switching cycles. The Soft Start pin is held low until 4096 cycles have been completed. The OCP signal resets and the converter recovers. After every soft start cycle, the converter stays in this mode until the overload or short circuit is removed.

The OCP circuit starts sampling current typically 160 ns after the low gate drive rises to about 3V. This delay functions to filter out switching noise.

### Thermal Shutdown

Temperature sensing is provided inside IR3843A. The trip threshold is typically set to 140°C. When trip threshold is exceeded, thermal shutdown turns off both MOSFETs and discharges the soft start capacitor.

Automatic restart is initiated when the sensed temperature drops within the operating range. There is a 20°C hysteresis in the thermal shutdown threshold.

### Output Voltage Sequencing

The IR3843A can accommodate user programmable sequencing using Seq, Enable and Power Good pins.

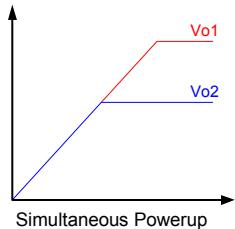


Fig. 8a. Simultaneous Power-up of the slave with respect to the master.

Through these pins, voltage sequencing such as simultaneous and sequential can be implemented. Figure 8. shows simultaneous sequencing configurations. In simultaneous power-up, the voltage at the Seq pin of the slave reaches 0.7V before the Fb pin of the master. For  $R_E/R_F = R_C/R_D$ , therefore, the output voltage of the slave follows that of the master until the voltage at the Seq pin of the slave reaches 0.7 V. After the voltage at the Seq pin of the slave exceeds 0.85V, the internal 0.7V reference of the slave dictates its output voltage.

It is recommended that irrespective of the sequencing configuration used, the input voltage should be allowed to come up to its nominal value first, followed by  $V_{cc}$  and Enable, before the sequencing signal is applied.

For non-sequenced operation, the Seq pin should be tied to a voltage greater than 0.85V, such as 3.3V or  $V_{cc}$ . Again, the input voltage should be allowed to come up before  $V_{cc}$  and Enable.

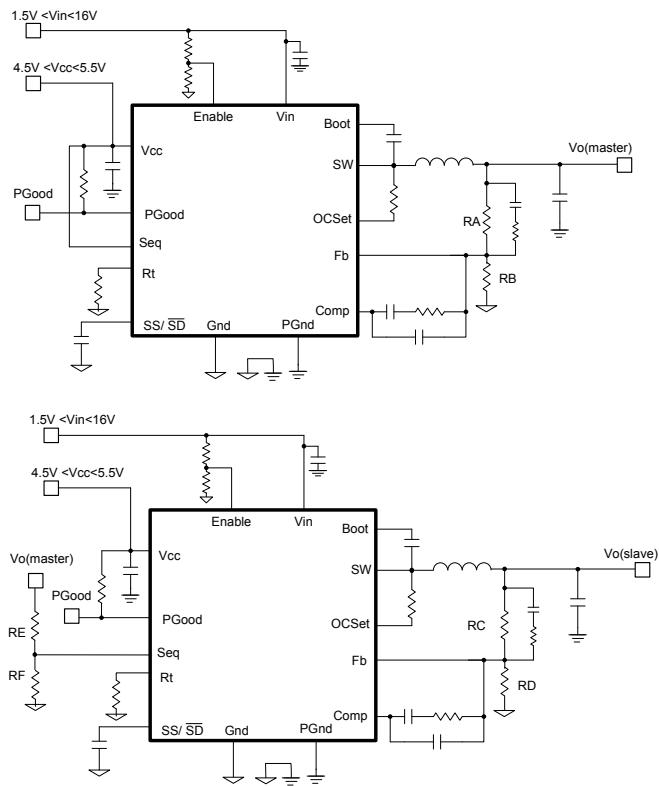


Fig. 8b. Application Circuit for Simultaneous Sequencing

### Power Good Output

The IC continually monitors the output voltage via Feedback (Fb pin). The feedback voltage forms an input to a window comparator whose upper and lower thresholds are 0.805V and 0.595V respectively. Hence, the Power Good signal is flagged when the Fb pin voltage is within the PGGood window, i. e., between 0.595V to 0.805V, as shown in Fig .9. The PGGood pin is open drain and it needs to be externally pulled high. High state indicates that output is in regulation. Fig. 9a shows the PGGood timing diagram for non-tracking operation. In this case, during startup, PGGood goes high after the SS voltage reaches 2.1V if the Fb voltage is within the PGGood comparator window. Fig. 9a. and Fig 9.b. also show a 256 cycle delay between the Fb voltage entering within the thresholds defined by the PGGood window and PGGood going high.

### TIMING DIAGRAM OF PGOOD FUNCTION

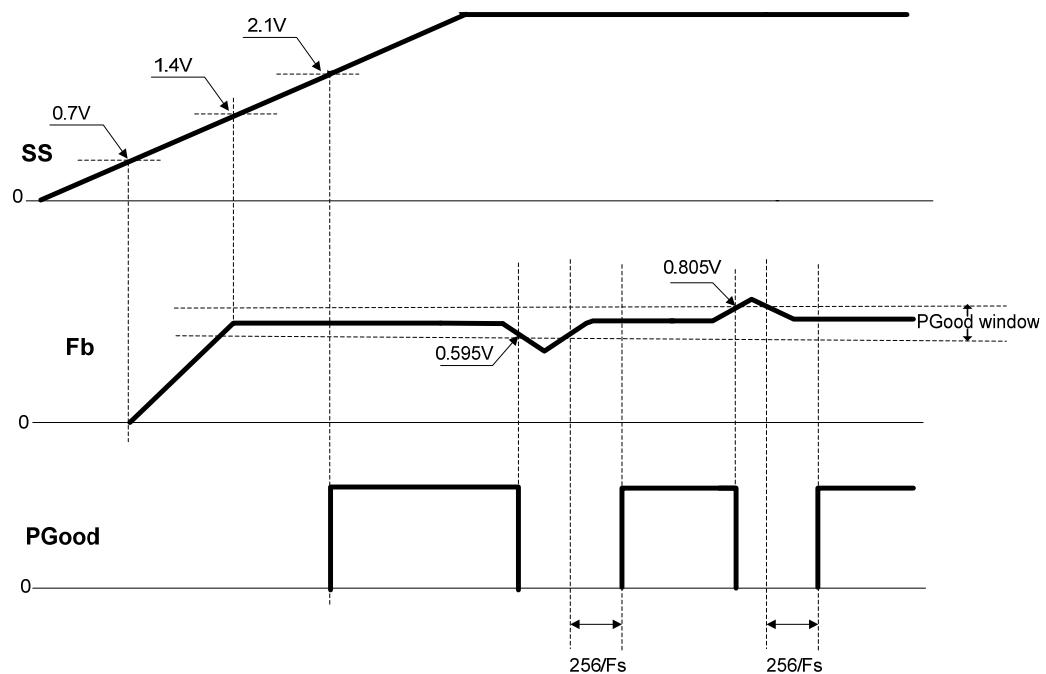


Fig.9a IR3843A Non-Tracking Operation (Seq=Vcc)

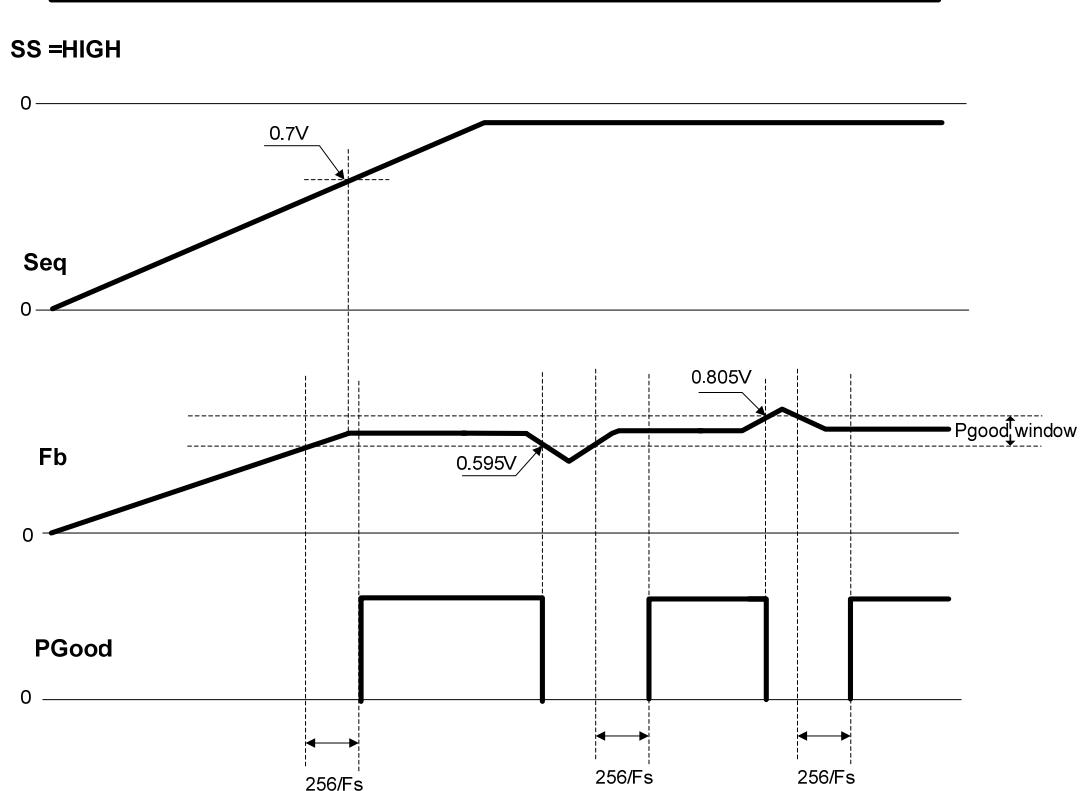


Fig.9b IR3843A Tracking Operation

### Minimum on time Considerations

The minimum ON time is the shortest amount of time for which the Control FET may be reliably turned on, and this depends on the internal timing delays. For the IR3843A, the typical minimum on-time is specified as 100 ns.

Any design or application using the IR3843A must ensure operation with a pulse width that is higher than this minimum on-time and preferably higher than 150 ns. This is necessary for the circuit to operate without jitter and pulse-skipping, which can cause high inductor current ripple and high output voltage ripple.

$$t_{on} = \frac{D}{F_s}$$

$$= \frac{V_{out}}{V_{in} \times F_s}$$

In any application that uses the IR3843A, the following condition must be satisfied:

$$t_{on(min)} \leq t_{on}$$

$$\therefore t_{on(min)} \leq \frac{V_{out}}{V_{in} \times F_s}$$

$$\therefore V_{in} \times F_s \leq \frac{V_{out}}{t_{on(min)}}$$

The minimum output voltage is limited by the reference voltage and hence  $V_{out(min)} = 0.7$  V. Therefore, for  $V_{out(min)} = 0.7$  V,

$$\therefore V_{in} \times F_s \leq \frac{V_{out(min)}}{t_{on(min)}}$$

$$\therefore V_{in} \times F_s \leq \frac{0.7 \text{ V}}{150 \text{ ns}} = 4.67 \times 10^6 \text{ V/s}$$

Therefore, even at the minimum switching frequency 250 kHz, no input voltage higher than 18.5V may be reliably converted down to 0.7V without excessive jitter or pulse skipping over the complete load range.

In general, practical considerations dictate that any application that demands a pulse width smaller than 175ns may not exhibit jitter free operation over the entire load range.

### Maximum Duty Ratio Considerations

A fixed off-time of 200 ns maximum is specified for the IR3843A. This provides an upper limit on the operating duty ratio at any given switching frequency. It is clear that, higher the switching frequency, the lower is the maximum duty ratio at which the IR3843A can operate. To allow a margin of 50ns, the maximum operating duty ratio in any application using the IR3843A should still accommodate about 250 ns off-time. Fig 10. shows a plot of the maximum duty ratio v/s the switching frequency, with 250 ns off-time.

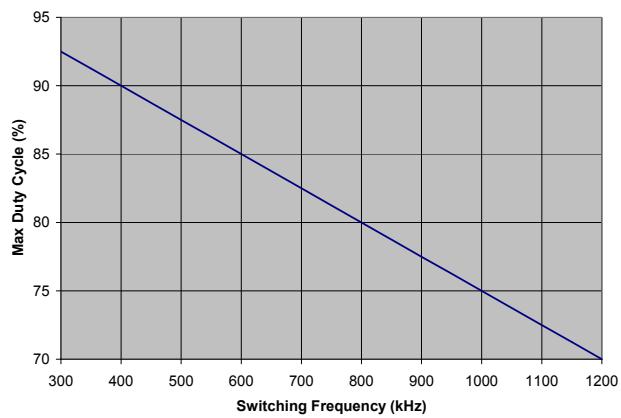


Fig. 10. Maximum duty cycle v/s switching frequency.

## Application Information

### Design Example:

The following example is a typical application for IR3843A. The application circuit is shown on page 23.

$$V_{in} = 12 \text{ V (13.2V max)}$$

$$V_o = 1.8 \text{ V}$$

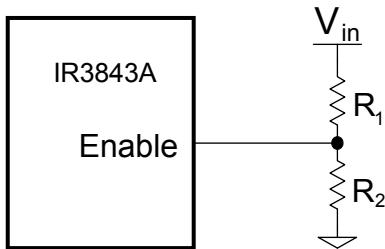
$$I_o = 3 \text{ A}$$

$$\Delta V_o \leq 54 \text{ mV}$$

$$F_s = 600 \text{ kHz}$$

### Enabling the IR3843A

As explained earlier, the precise threshold of the Enable lends itself well to implementation of a UVLO for the Bus Voltage.



For a typical Enable threshold of  $V_{EN} = 1.2 \text{ V}$

$$V_{in(\min)} * \frac{R_2}{R_1 + R_2} = V_{EN} = 1.2 \quad (5)$$

$$R_2 = R_1 \frac{V_{EN}}{V_{in(\min)} - V_{EN}} \quad (6)$$

For a  $V_{in(\min)} = 10.2 \text{ V}$ ,  $R_1 = 49.9 \text{ k}\Omega$  and  $R_2 = 7.5 \text{ k}\Omega$  is a good choice.

### Programming the frequency

For  $F_s = 600 \text{ kHz}$ , select  $R_t = 23.7 \text{ k}\Omega$ , using Table. 1.

### Output Voltage Programming

Output voltage is programmed by reference voltage and external voltage divider. The Fb pin is the inverting input of the error amplifier, which is internally referenced to 0.7V. The divider is ratioed to provide 0.7V at the Fb pin when the output is at its desired value. The output voltage is defined by using the following equation:

$$V_o = V_{ref} * \left( 1 + \frac{R_8}{R_9} \right) \quad (7)$$

when an external resistor divider is connected to the output as shown in figure 11.

Equation (7) can be rewritten as:

$$R_9 = R_8 * \left( \frac{V_{ref}}{V_o - V_{ref}} \right) \quad (8)$$

For the calculated values of R8 and R9 see feedback compensation section.

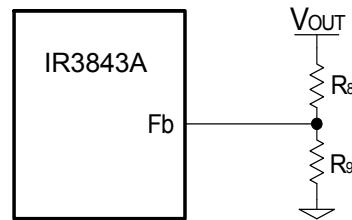


Fig. 11. Typical application of the IR3843A for programming the output voltage

### Soft-Start Programming

The soft-start timing can be programmed by selecting the soft-start capacitance value. From (1), for a desired start-up time of the converter, the soft start capacitor can be calculated by using:

$$C_{SS} (\mu\text{F}) = T_{start} (\text{ms}) \times 0.02857 \quad (9)$$

Where  $T_{start}$  is the desired start-up time (ms).

For a start-up time of 3.5ms, the soft-start capacitor will be  $0.099 \mu\text{F}$ . Choose a  $0.1 \mu\text{F}$  ceramic capacitor.

### Bootstrap Capacitor Selection

To drive the Control FET, it is necessary to supply a gate voltage at least 4V greater than the voltage at the SW pin, which is connected to the source of the Control FET. This is achieved by using a bootstrap configuration, which comprises the internal bootstrap diode and an external bootstrap capacitor (C6), as shown in Fig.12. The operation of the circuit is as follows: When the lower MOSFET is turned on, the capacitor node connected to SW is pulled down to ground. The capacitor charges towards  $V_{cc}$  through the internal bootstrap diode, which has a forward voltage drop  $V_D$ . The voltage  $V_c$  across the bootstrap capacitor C6 is approximately given as

$$V_c \approx V_{cc} - V_D \quad (10)$$

When the upper MOSFET turns on in the next cycle, the capacitor node connected to SW rises to the bus voltage  $V_{in}$ . However, if the value of C6 is appropriately chosen,

the voltage  $V_c$  across  $C_6$  remains approximately unchanged and the voltage at the Boot pin becomes

$$V_{Boot} \approx V_{in} + V_{cc} - V_D \quad \dots \dots \dots (11)$$

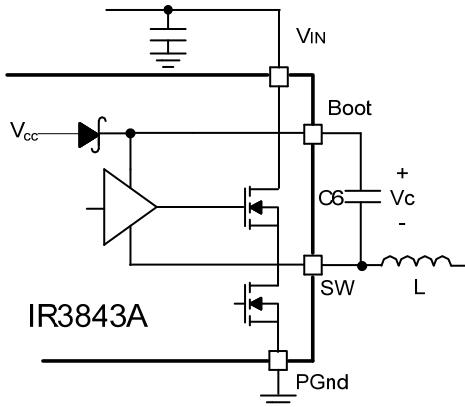


Fig. 12. Bootstrap circuit to generate  $V_c$  voltage

A bootstrap capacitor of value 0.1uF is suitable for most applications.

For applications with 21V input voltage, the switch node may ring above the 25V absolute maximum voltage rating. To prevent this, in addition to using best layout practices, it may be necessary to provide a 10 ohm resistor in series with the boot capacitor.

### Input Capacitor Selection

The ripple current generated during the on time of the upper MOSFET should be provided by the input capacitor. The RMS value of this ripple is expressed by:

$$I_{RMS} = I_o * \sqrt{D * (1 - D)} \quad \dots \dots \dots (12)$$

$$D = \frac{V_o}{V_{in}} \quad \dots \dots \dots (13)$$

Where:

$D$  is the Duty Cycle

$I_{RMS}$  is the RMS value of the input capacitor current.

$I_o$  is the output current.

For  $I_o = 3A$  and  $D = 0.15$ , the  $I_{RMS} = 1.07A$ .

Ceramic capacitors are recommended due to their peak current capabilities. They also feature low ESR and ESL at higher frequency which enables better efficiency. For this application, it is

advisable to have 1x10uF 25V ceramic capacitors C3216X5R1E106M from TDK. In addition to these, although not mandatory, a 1X330uF, 25V SMD capacitor EEV-FK1E331P may also be used as a bulk capacitor and is recommended if the input power supply is not located close to the converter.

### Inductor Selection

The inductor is selected based on output power, operating frequency and efficiency requirements. A low inductor value causes large ripple current, resulting in the smaller size, faster response to a load transient but poor efficiency and high output noise. Generally, the selection of the inductor value can be reduced to the desired maximum ripple current in the inductor ( $\Delta i$ ). The optimum point is usually found between 20% and 50% ripple of the output current.

For the buck converter, the inductor value for the desired operating ripple current can be determined using the following relation:

$$V_{in} - V_o = L * \frac{\Delta i}{\Delta t}; \quad \Delta t = D * \frac{1}{F_s} \quad \dots \dots \dots (14)$$

$$L = (V_{in} - V_o) * \frac{V_o}{V_{in} * \Delta i * F_s}$$

Where:

$V_{in}$  = Maximum input voltage

$V_o$  = Output Voltage

$\Delta i$  = Inductor ripple current

$F_s$  = Switching frequency

$\Delta t$  = Turn on time

$D$  = Duty cycle

If  $\Delta i \approx 40\% (I_o)$ , then the output inductor is calculated to be  $2.13\mu\text{H}$ . Select  $L=2.2\mu\text{H}$ .

The PCMB065T-2R2MS from Vishay provides a compact, low profile inductor suitable for this application

## Output Capacitor Selection

The voltage ripple and transient requirements determine the output capacitors type and values. The criteria is normally based on the value of the Effective Series Resistance (ESR). However the actual capacitance value and the Equivalent Series Inductance (ESL) are other contributing components. These components can be described as

$$\Delta V_o = \Delta V_{o(ESR)} + \Delta V_{o(ESL)} + \Delta V_{o(C)}$$

$$\Delta V_{o(ESR)} = \Delta I_L * ESR$$

$$\Delta V_{o(ESL)} = \left( \frac{V_{in} - V_o}{L} \right) * ESL$$

$$\Delta V_{o(C)} = \frac{\Delta I_L}{8 * C_o * F_s} \quad \dots \dots \dots (15)$$

$\Delta V_o$  = Output voltage ripple

$\Delta I_L$  = Inductor ripple current

Since the output capacitor has a major role in the overall performance of the converter and determines the result of transient response, selection of the capacitor is critical. The IR3843A can perform well with all types of capacitors.

As a rule, the capacitor must have low enough ESR to meet output ripple and load transient requirements.

The goal for this design is to meet the voltage ripple requirement in the smallest possible capacitor size. Therefore it is advisable to select ceramic capacitors due to their low ESR and ESL and small size. Three of the Panasonic ECJ-2FB0J226ML (22uF, 6.3V, 3mOhm) capacitors is a good choice.

## Feedback Compensation

The IR3843A is a voltage mode controller. The control loop is a single voltage feedback path including error amplifier and error comparator. To achieve fast transient response and accurate output regulation, a compensation circuit is necessary. The goal of the compensation network is to provide a closed-loop transfer function with the highest 0 dB crossing frequency and adequate phase margin (greater than 45°).

The output LC filter introduces a double pole, -40dB/decade gain slope above its corner resonant frequency, and a total phase lag of 180° (see figure 13). The resonant frequency of the LC filter is expressed as follows:

$$F_{LC} = \frac{1}{2 * \pi \sqrt{L_o * C_o}} \quad \dots \dots \dots (16)$$

Figure 13 shows gain and phase of the LC filter. Since we already have 180° phase shift from the output filter alone, the system runs the risk of being unstable.

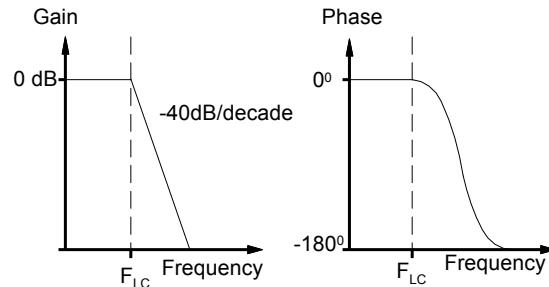


Fig. 13. Gain and Phase of LC filter

The IR3843A uses a voltage-type error amplifier with high-gain (110dB) and wide-bandwidth. The output of the amplifier is available for DC gain control and AC phase compensation.

The error amplifier can be compensated either in type II or type III compensation.

Local feedback with Type II compensation is shown in Fig. 14.

This method requires that the output capacitor should have enough ESR to satisfy stability requirements. In general the output capacitor's ESR generates a zero typically at 5kHz to 50kHz which is essential for an acceptable phase margin.

The ESR zero of the output capacitor is expressed as follows:

$$F_{ESR} = \frac{1}{2 * \pi * ESR * C_o} \quad \dots \dots \dots (17)$$

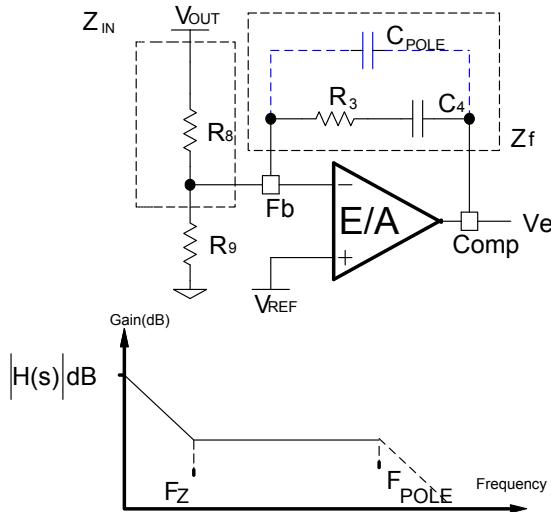


Fig. 14. Type II compensation network and its asymptotic gain plot

The transfer function ( $V_e/V_o$ ) is given by:

$$\frac{V_e}{V_o} = H(s) = -\frac{Z_f}{Z_{IN}} = -\frac{1+sR_3C_4}{sR_8C_4} \quad \dots(18)$$

The (s) indicates that the transfer function varies as a function of frequency. This configuration introduces a gain and zero, expressed by:

$$|H(s)| = \frac{R_3}{R_8} \quad \dots(19)$$

$$F_z = \frac{1}{2\pi * R_3 * C_4} \quad \dots(20)$$

First select the desired zero-crossover frequency ( $F_o$ ):

$$F_o > F_{ESR} \text{ and } F_o \leq (1/5 \sim 1/10) * F_s$$

Use the following equation to calculate R3:

$$R_3 = \frac{V_{osc} * F_o * F_{ESR} * R_8}{V_{in} * F_{LC}^2} \quad \dots(21)$$

Where:

$V_{in}$  = Maximum Input Voltage

$V_{osc}$  = Oscillator Ramp Voltage

$F_o$  = Crossover Frequency

$F_{ESR}$  = Zero Frequency of the Output Capacitor

$F_{LC}$  = Resonant Frequency of the Output Filter

$R_8$  = Feedback Resistor

To cancel one of the LC filter poles, place the zero before the LC filter resonant frequency pole:

$$F_z = 75\% F_{LC}$$

$$F_z = 0.75 * \frac{1}{2\pi * L_o * C_o} \quad \dots(22)$$

Use equations (20), (21) and (22) to calculate  $C_4$ .

One more capacitor is sometimes added in parallel with  $C_4$  and  $R_3$ . This introduces one more pole which is mainly used to suppress the switching noise.

The additional pole is given by:

$$F_p = \frac{1}{2\pi * R_3 * \frac{C_4 * C_{pole}}{C_4 + C_{pole}}} \quad \dots(23)$$

The pole sets to one half of the switching frequency which results in the capacitor  $C_{pole}$ :

$$C_{pole} = \frac{1}{\pi * R_3 * F_s - \frac{1}{C_4}} \approx \frac{1}{\pi * R_3 * F_s} \quad \dots(24)$$

For a general solution for unconditional stability for any type of output capacitors, and a wide range of ESR values, we should implement local feedback with a type III compensation network. The typically used compensation network for voltage-mode controller is shown in figure 15.

Again, the transfer function is given by:

$$\frac{V_e}{V_o} = H(s) = -\frac{Z_f}{Z_{IN}}$$

By replacing  $Z_{in}$  and  $Z_f$  according to figure 15, the transfer function can be expressed as:

$$H(s) = -\frac{(1+sR_3C_4)[1+sC_7(R_8 + R_{10})]}{sR_8(C_4 + C_3)[1+sR_3\left(\frac{C_4 * C_3}{C_4 + C_3}\right)][1+sR_{10}C_7]} \quad \dots(25)$$





**Application Diagram:**

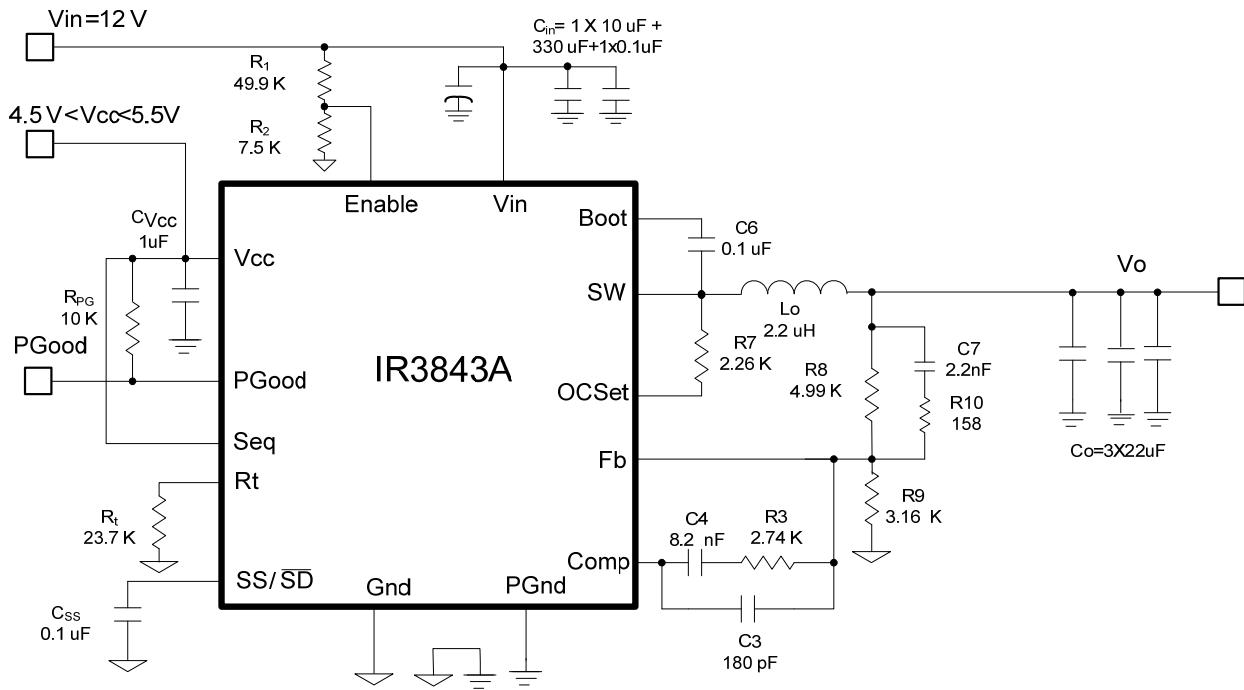


Fig. 16. Application circuit diagram for a 12V to 1.8 V, 3 A Point Of Load Converter

**Suggested Bill of Materials for the application circuit:**

Part Reference	Quantity	Value	Description	Manufacturer	Part Number
Cin	1	330uF	SMD Electrolytic, Fsize, 25V, 20%	Panasonic	EEV-FK1E331P
	1	10uF	1206, 16V, X5R, 20%	TDK	C3216X5R1E106M
	1	0.1uF	0603, 25V, X7R, 10%	Panasonic	ECJ-1VB1E104K
Lo	1	2.2uH	7x6.5x5mm, 20%, 8A	Cyntec	PCMB065T-2R2MS
Co	3	22uF	0805, 6.3V, X5R, 20%	Panasonic	ECJ-2FB0J226ML
R1	1	49.9k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX4992
R2	1	7.5k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX7501
Rt	1	23.7k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX2372
R <sub>ocset</sub>	1	2.26k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX2261
R <sub>PG</sub>	1	10k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX1002
C <sub>ss</sub> C <sub>6</sub>	2	0.1uF	0603, 25V, X7R, 10%	Panasonic	ECJ-1VB1E104K
R3	1	2.74k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX2741
C3	1	180pF	50V, 0603, NPO, 5%	Panasonic	ECJ-1VC1H181J
C4	1	8.2nF	0603, 50V, X7R, 10%	Panasonic	ECJ-1VB1H822K
R8	1	4.99k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX4991
R9	1	3.16k	Thick Film, 0603, 1/10W, 1%	Rohm	MCR03EZPFX3161
R10	1	158	Thick Film, 0603, 1/10W, 1%	Rohm	ERJ-3EKF1580V
C <sub>Vcc</sub>	1	1.0uF	0603, 16V, X5R, 20%	Panasonic	ECJ-BVB1C105M
U1	1	IR3843A	SupiRBuck, 3A, PQFN 5x6mm	International Rectifier	IR3843AMPbF

**TYPICAL OPERATING WAVEFORMS**

**V<sub>in</sub>=12.0V, V<sub>cc</sub>=5V, V<sub>o</sub>=1.8V, I<sub>o</sub>=0-3A, Room Temperature, No Air Flow**

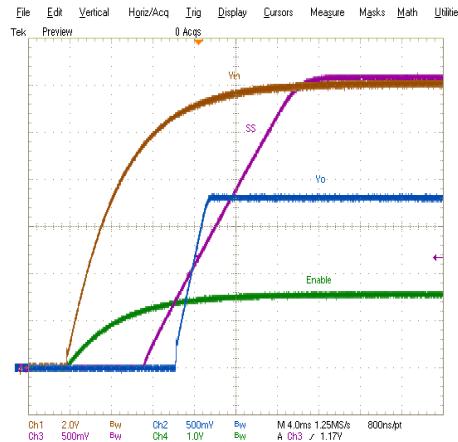


Fig. 17. Start up at 3A Load  
Ch<sub>1</sub>:V<sub>in</sub>, Ch<sub>2</sub>:V<sub>o</sub>, Ch<sub>3</sub>:V<sub>ss</sub>, Ch<sub>4</sub>:Enable

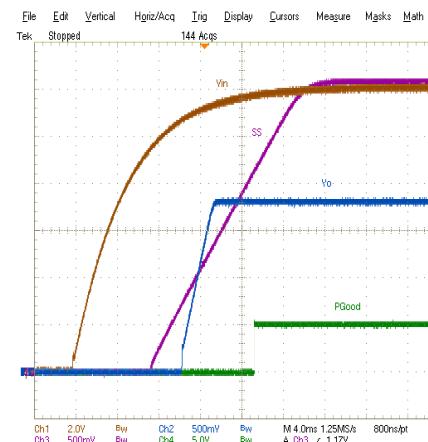


Fig. 18. Start up at 3A Load,  
Ch<sub>1</sub>:V<sub>in</sub>, Ch<sub>2</sub>:V<sub>o</sub>, Ch<sub>3</sub>:V<sub>ss</sub>, Ch<sub>4</sub>:V<sub>PGood</sub>

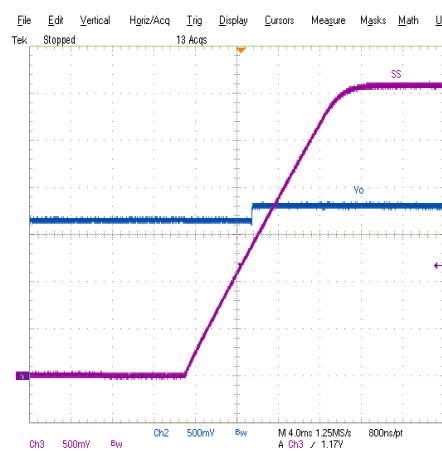


Fig. 19. Start up with 1.62V Pre  
Bias, 0A Load, Ch<sub>2</sub>:V<sub>o</sub>, Ch<sub>3</sub>:V<sub>ss</sub>

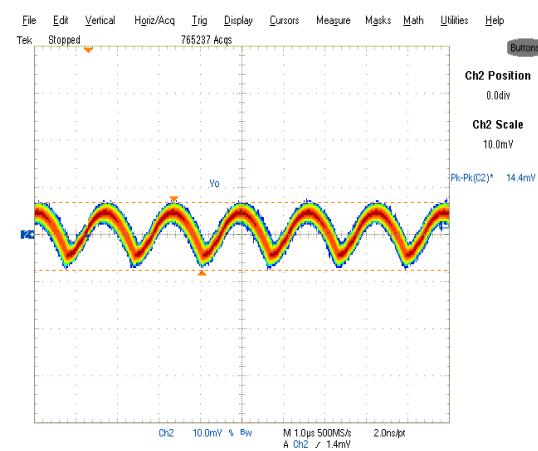


Fig. 20. Output Voltage Ripple, 3A  
load Ch<sub>2</sub>:V<sub>o</sub>

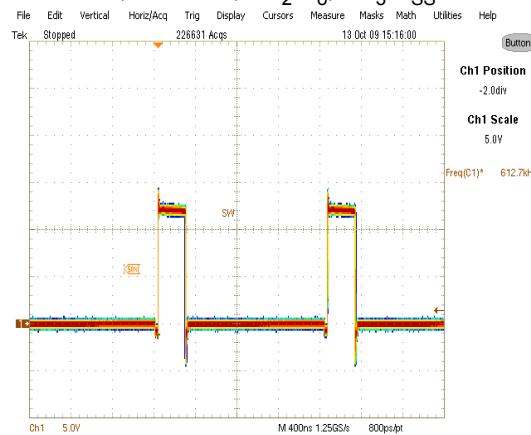


Fig. 21. Inductor node at 3A load  
Ch<sub>1</sub>:LX

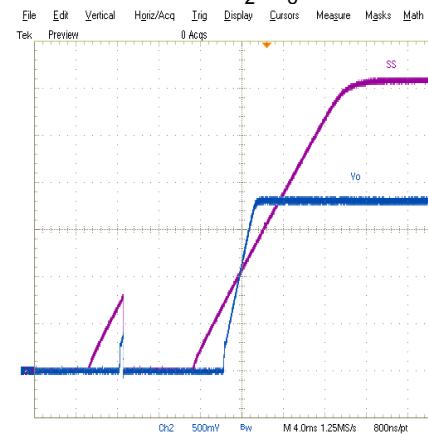


Fig. 22. Short (Hiccup) Recovery  
Ch<sub>2</sub>:V<sub>o</sub>, Ch<sub>3</sub>:V<sub>ss</sub>

**TYPICAL OPERATING WAVEFORMS**

**V<sub>in</sub>=12V, V<sub>cc</sub>=5V, V<sub>o</sub>=1.8V, I<sub>o</sub>=1.5A-3A, Room Temperature, No Air Flow**

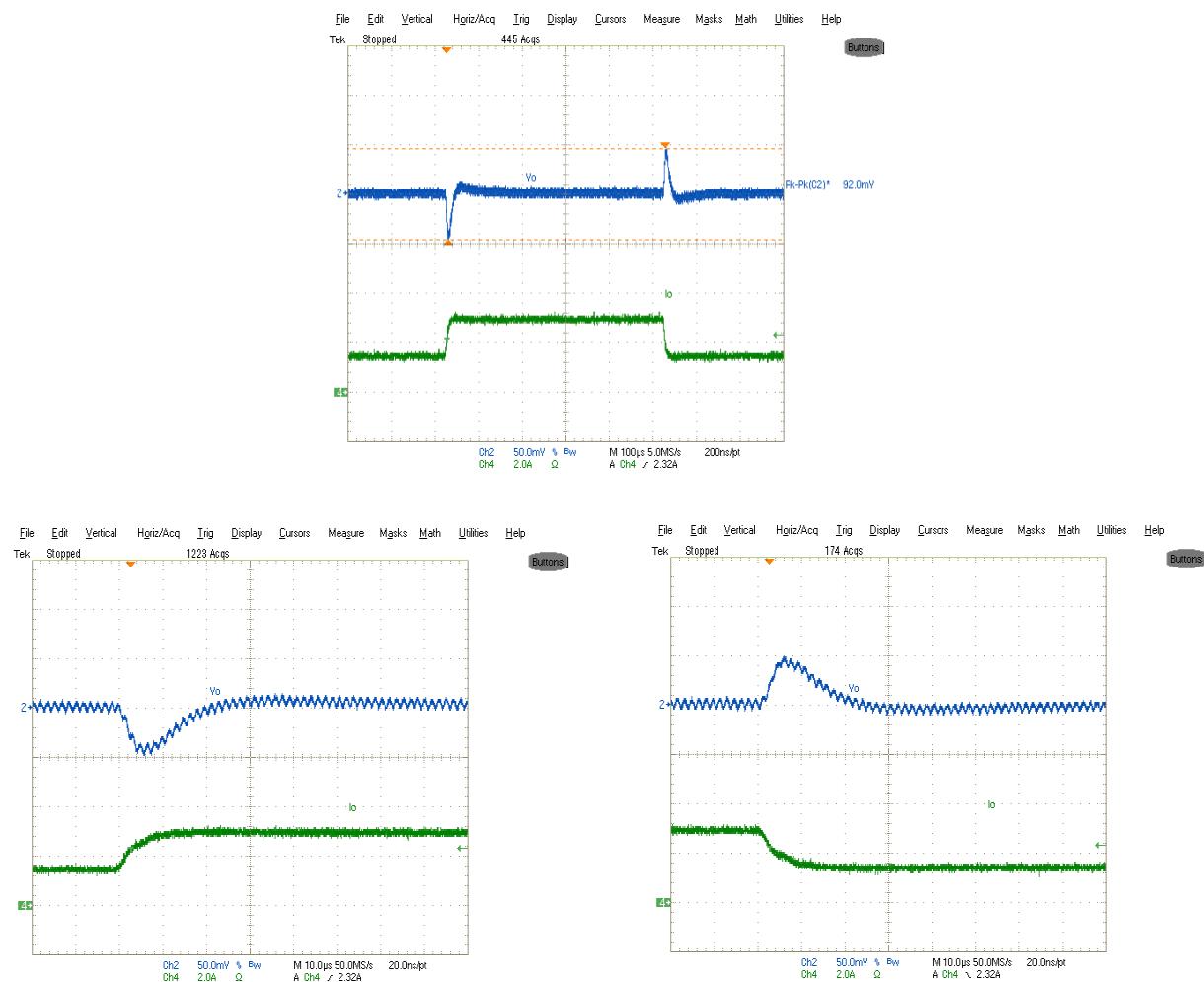


Fig. 23. Transient Response, 1.5A to 3A step  
2.5A/μs  
Ch<sub>2</sub>:V<sub>o</sub>, Ch<sub>4</sub>:I<sub>o</sub>

**TYPICAL OPERATING WAVEFORMS**  
**V<sub>in</sub>=12V, V<sub>cc</sub>=5V, V<sub>o</sub>=1.8V, I<sub>o</sub>=3A, Room Temperature, No Air Flow**

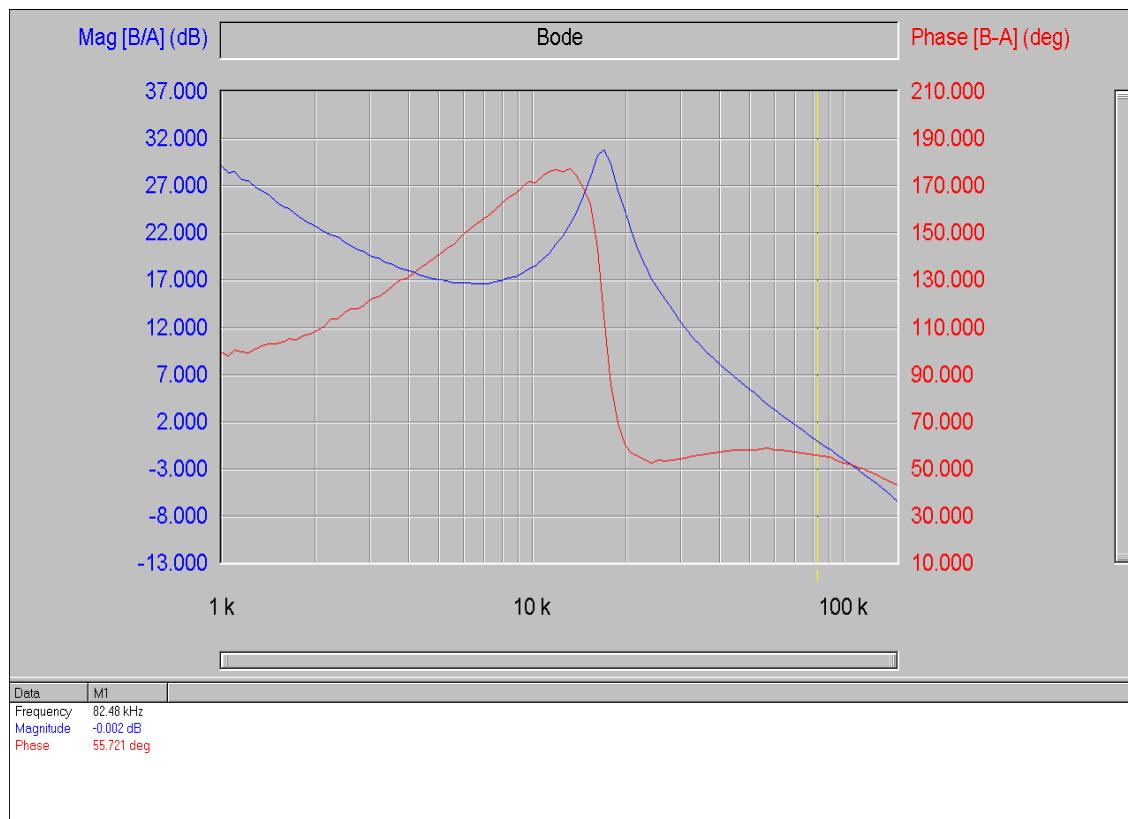


Fig. 24. Bode Plot at 3A load shows a bandwidth of 82kHz and phase margin of 56 degrees

**Simultaneous Tracking at Power Up and Power Down**  
**V<sub>in</sub>=12V, V<sub>o</sub>=1.8V, I<sub>o</sub>=3A, Room Temperature, No Air Flow**

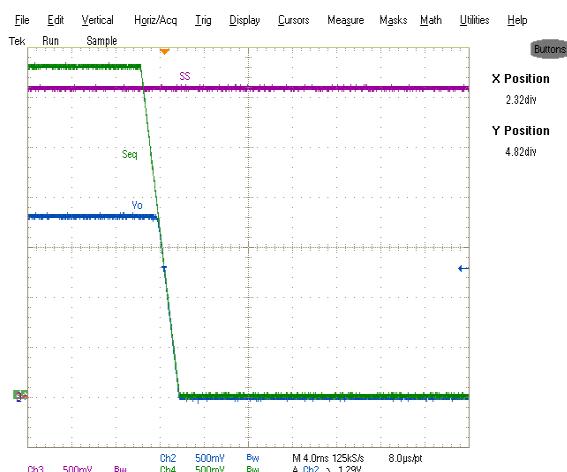
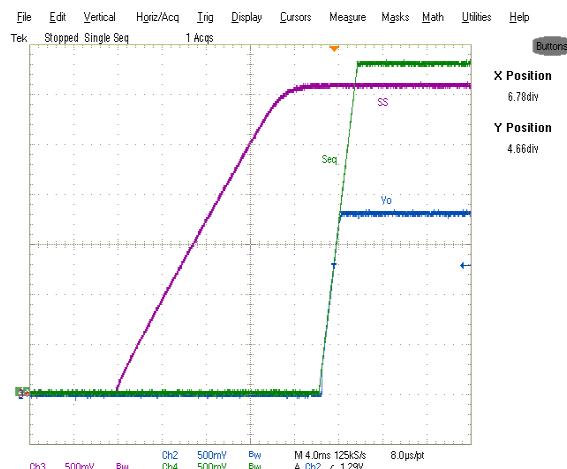
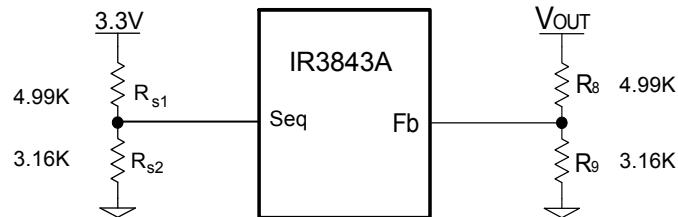


Fig. 25: Simultaneous Tracking a 3.3V input at power-up and shut-down  
 Ch2: V<sub>out</sub> Ch3:SS Ch4: Seq

Feedback  
trace should  
be kept  
away from  
noise  
sources

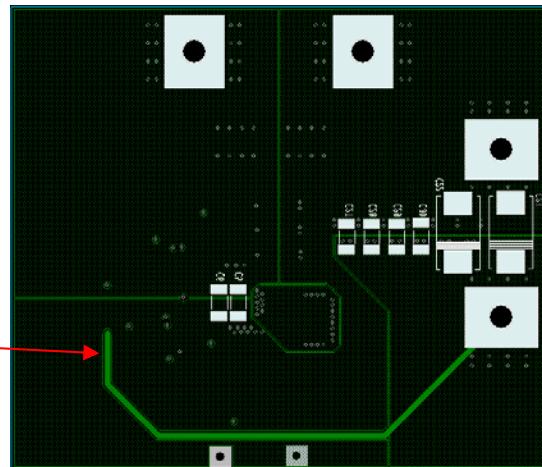


Fig. 26b. IRDC3843A demoboard layout considerations – Bottom Layer

Analog  
Ground  
plane  
Single point  
connection between  
AGND & PGND,  
should be close to  
the SupIRBuck, kept  
away from noise  
sources.

Power  
Ground  
Plane

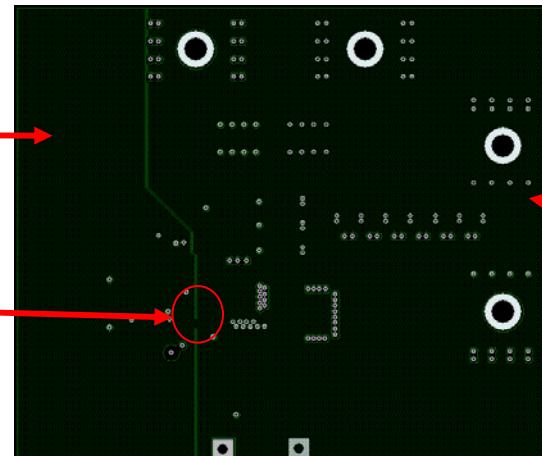


Fig. 26c. IRDC3843A demoboard layout considerations – Mid Layer 1

Use separate traces  
for connecting Boot  
cap and Rocsset to the  
switch node and with  
the minimum length  
traces. Avoid big  
loops.

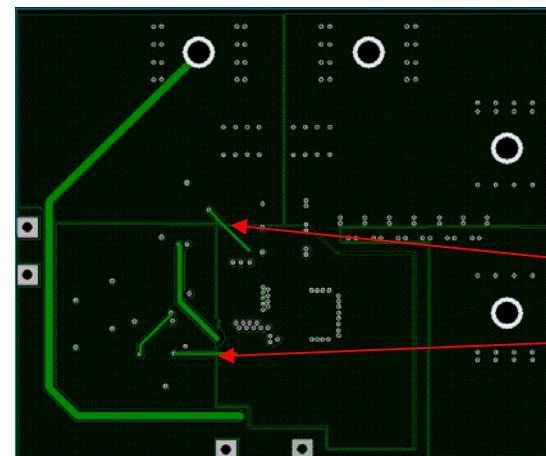


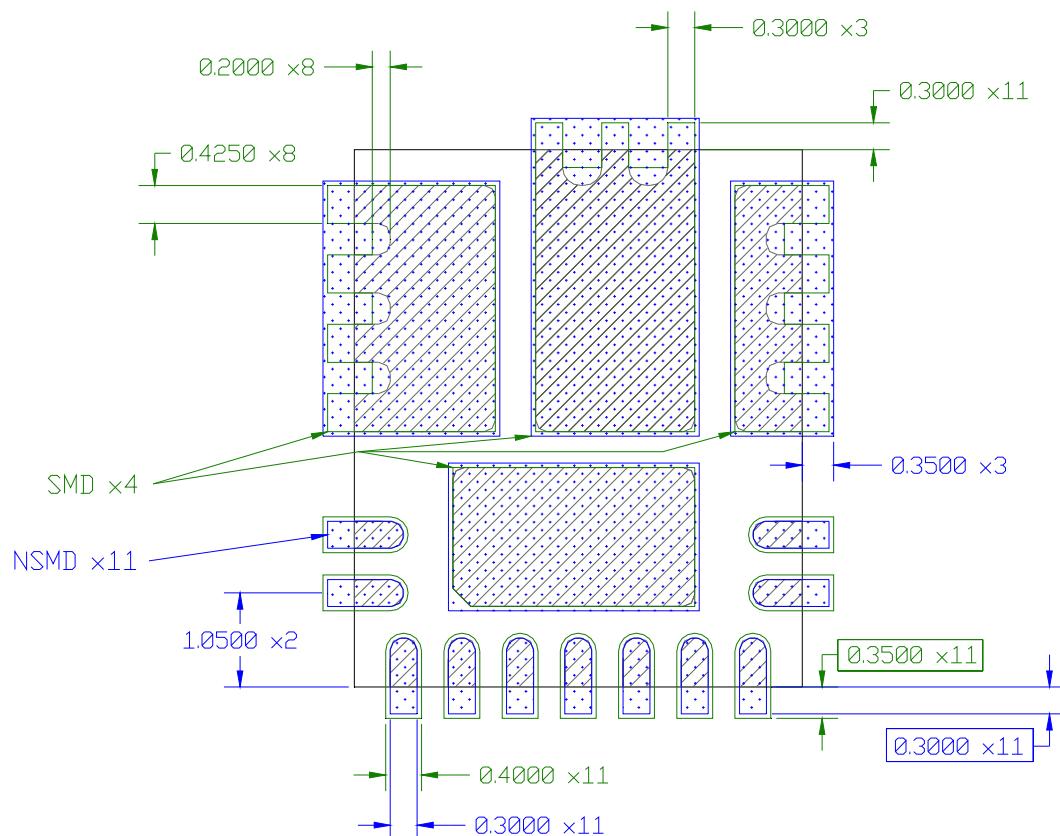
Fig. 26d. IRDC3843A demoboard layout considerations – Mid Layer 2

### PCB Metal and Components Placement

Lead lands (the 11 IC pins) width should be equal to nominal part lead width. The minimum lead to lead spacing should be  $\geq 0.2\text{mm}$  to minimize shorting.

Lead land length should be equal to maximum part lead length + 0.3 mm outboard extension. The outboard extension ensures a large and inspectable toe fillet.

Pad lands (the 4 big pads other than the 11 IC pins) length and width should be equal to maximum part pad length and width. However, the minimum metal to metal spacing should be no less than 0.17mm for 2 oz. Copper; no less than 0.1mm for 1 oz. Copper and no less than 0.23mm for 3 oz. Copper.



All Dimensions in mm

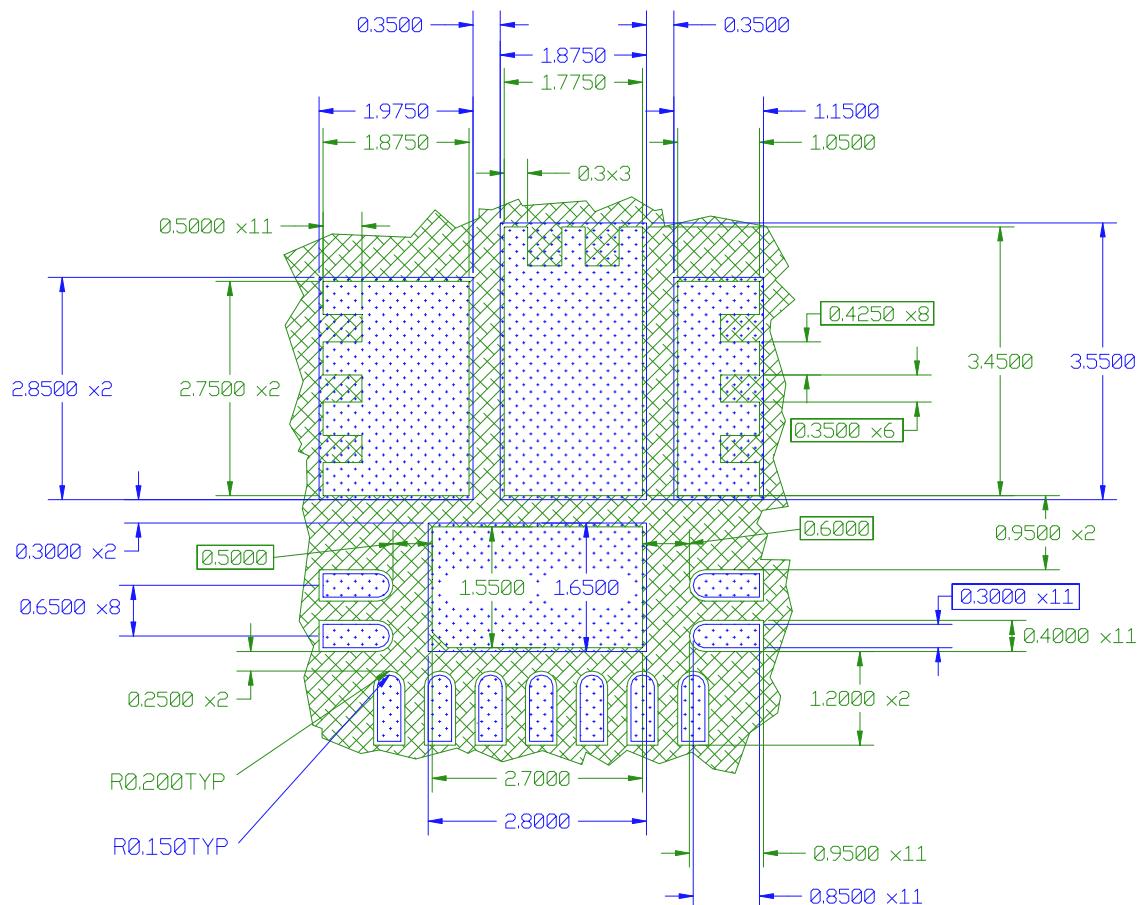


## Solder Resist

It is recommended that the lead lands are Non Solder Mask Defined (NSMD). The solder resist should be pulled away from the metal lead lands by a minimum of 0.025mm to ensure NSMD pads.

The land pad should be Solder Mask Defined (SMD), with a minimum overlap of the solder resist onto the copper of 0.05mm to accommodate solder resist mis-alignment.

Ensure that the solder resist in-between the lead lands and the pad land is  $\geq 0.15\text{mm}$  due to the high aspect ratio of the solder resist strip separating the lead lands from the pad land.



All Dimensions in mm

**NOTE:**



## PCB Copper



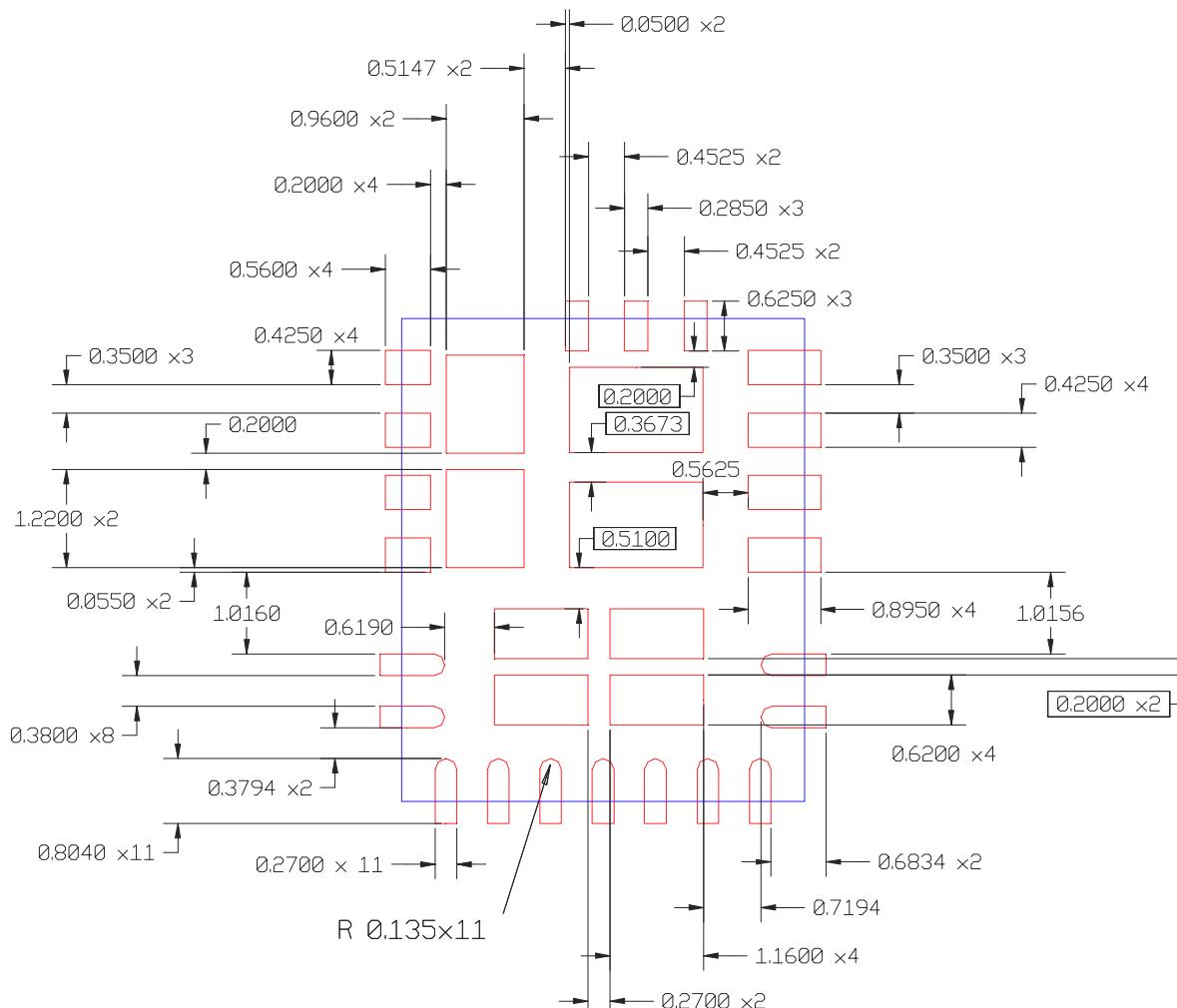
## PCB Solder Resist

11x Signal Pins are NSMD

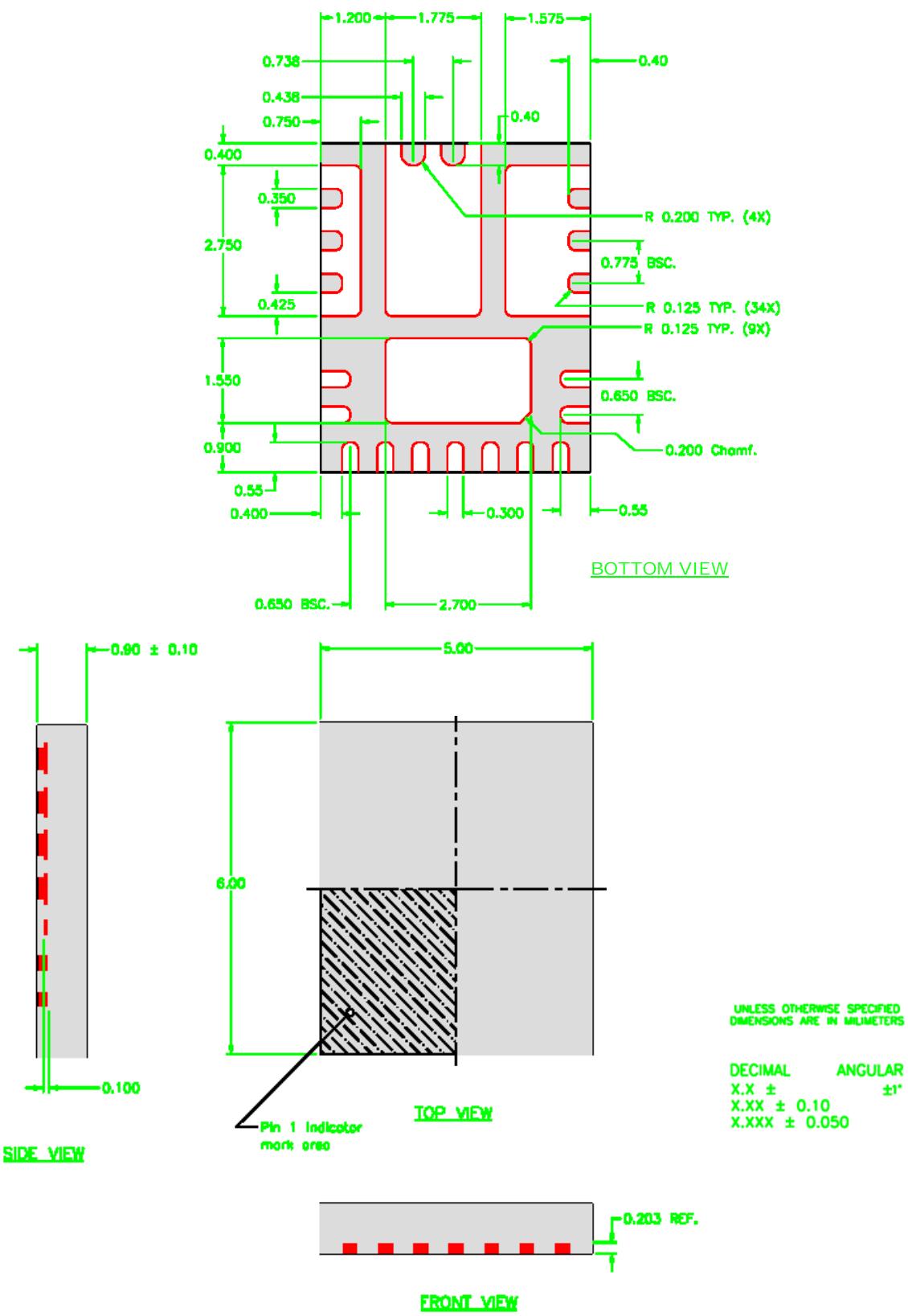
4x Power Pins are SMD

## Stencil Design

- The Stencil apertures for the lead lands should be approximately 80% of the area of the lead lads. Reducing the amount of solder deposited will minimize the occurrences of lead shorts. If too much solder is deposited on the center pad the part will float and the lead lands will be open.
- The maximum length and width of the land pad stencil aperture should be equal to the solder resist opening minus an annular 0.2mm pull back to decrease the incidence of shorting the center land to the lead lands when the part is pushed into the solder paste.



Stencil Aperture  
All Dimensions in mm



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 TAC Fax: (310) 252-7903

This product has been designed and qualified for the Industrial market (Note5)  
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 Data and specifications subject to change without notice. 08/12